

Quad Channel, 16-Bit, Serial Input, 4 mA to 20 mA and Voltage Output DAC, Dynamic Power Control, HART Connectivity

AD5755-1

FEATURES

16-bit resolution and monotonicity

Dynamic power control for thermal management

Current and voltage output pins connectable to a single terminal

Current output ranges: 0 mA to 20 mA, 4 mA to 20 mA, or 0 mA to 24 mA

±0.05% total unadjusted error (TUE) maximum

Voltage output ranges (with 20% overrange): 0 V to 5 V, 0 V to 10 V, \pm 5 V, and \pm 10 V

±0.04% total unadjusted error (TUE) maximum

User programmable offset and gain

On-chip diagnostics

On-chip reference (±10 ppm/°C maximum)

-40°C to +105°C temperature range

APPLICATIONS

Process control Actuator control PLCs

HART network connectivity

GENERAL DESCRIPTION

The AD5755-1 is a quad, voltage and current output DAC that operates with a power supply range from -26.4 V to +33 V. On-chip dynamic power control minimizes package power

dissipation in current mode. This is achieved by regulating the voltage on the output driver from 7.4 V to 29.5 V using a dc-to-dc boost converter optimized for minimum on-chip power dissipation. Each channel has a corresponding CHART pin so that HART signals can be coupled onto the current output of the AD5755-1.

The part uses a versatile 3-wire serial interface that operates at clock rates of up to 30 MHz and is compatible with standard SPI, QSPI™, MICROWIRE™, DSP, and microcontroller interface standards. The interface also features optional CRC-8 packet error checking, as well as a watchdog timer that monitors activity on the interface.

PRODUCT HIGHLIGHTS

- 1. Dynamic power control for thermal management.
- 2. 16-bit performance.
- 3. Multichannel.
- 4. HART compliant.

COMPANION PRODUCTS

Product Family: AD5755, AD5757 External References: ADR445, ADR02 Digital Isolators: ADuM1410, ADuM1411

Power: ADP2302, ADP2303

Additional companion products on the AD5755-1 product page

FUNCTIONAL BLOCK DIAGRAM

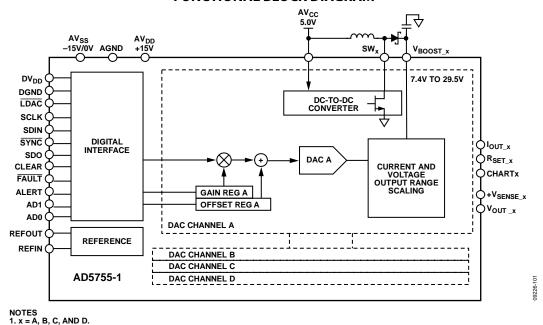


Figure 1.

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5/11—Rev. 0 to Rev. A
Removed Endnote 6 (Table 1)
Changed AV _{DD} Minimum Value from 10.8 V to 9 V Changed AIss Minimum Value from -1.4 mA to -1.7 mA
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DETAILED FUNCTIONAL BLOCK DIAGRAM

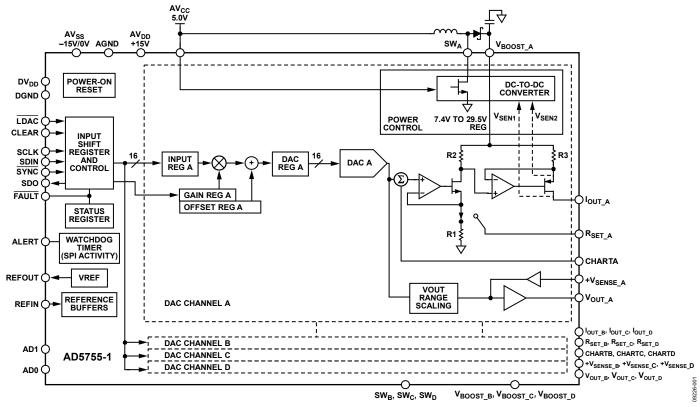


Figure 2.

SPECIFICATIONS

 $AV_{DD} = V_{BOOST_x} = 15 \text{ V}; \ AV_{SS} = -15 \text{ V}/0 \text{ V}; \ DV_{DD} = 2.7 \text{ V} \text{ to } 5.5 \text{ V}; \ AV_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}; \ dc\text{-to-dc converter disabled}; \ AGND = DGND = GNDSW_x = 0 \text{ V}; \ REFIN = 5 \text{ V}; \ voltage \ outputs} : R_L = 1 \text{ k}\Omega, \ C_L = 220 \text{ pF}; \ current \ outputs} : R_L = 300 \ \Omega; \ all \ specifications \ T_{MIN} \ to \ T_{MAX}, \ unless \ otherwise \ noted.$

Table 1.

Parameter ¹	Min	Тур	Max	Unit	Test Conditions/Comments
VOLTAGE OUTPUT					
Output Voltage Ranges	0		5	V	
	0		10	V	AV _{DD} must have minimum 2.2 V headroom on output
	-5		+5	V	
	-10		+10	V	AV _{DD} /AV _{SS} must have minimum 2.2 V headroom on output
	0		6	V	·
	0		12	V	AV _{DD} must have minimum 2.2 V headroom on output
	-6		+6	V	
	-12		+12	V	AV _{DD} /AV _{SS} must have minimum 2.2 V headroom on output
ACCURACY BIPOLAR SUPPLY					$AV_{SS} = -15 \text{ V}$, loaded and unloaded
Resolution	16			Bits	
Total Unadjusted Error (TUE)	-0.04		+0.04	% FSR	
	-0.03	±0.0032	+0.03	% FSR	T _A = 25°C
TUE Long-Term Stability		35		ppm FSR	Drift after 1000 hours, T _J = 150°C
Relative Accuracy (INL)	-0.006	±0.0012	+0.006	% FSR	0 V to 5 V, 0 V to 10 V, ±5 V, ±10 V ranges
	-0.008	±0.0012	+0.008	% FSR	On overranges
Differential Nonlinearity (DNL)	-1		+1	LSB	Guaranteed monotonic
Zero-Scale Error	-0.03	±0.002	+0.03	% FSR	
Zero-Scale TC ²		±2		ppm FSR/°C	
Bipolar Zero Error	-0.03	±0.002	+0.03	% FSR	
Bipolar Zero TC ²		±1		ppm FSR/°C	
Offset Error	-0.03	±0.002	+0.03	% FSR	
Offset TC ²		±2		ppm FSR/°C	
Gain Error	-0.03	±0.004	+0.03	% FSR	
Gain TC ²		±3		ppm FSR/°C	
Full-Scale Error	-0.03	±0.002	+0.03	% FSR	
Full-Scale TC ²		±2		ppm FSR/°C	
ACCURACY UNIPOLAR SUPPLY ²					$AV_{SS} = 0 V$
Total Unadjusted Error (TUE)	-0.06	±0.025	+0.06	% FSR	
Relative Accuracy (INL) ³	-0.009		+0.009	% FSR	
Differential Nonlinearity (DNL)	-1		+1	LSB	Guaranteed monotonic
Zero-Scale Error		+0.22		% FSR	
Offset Error	-0.07	±0.025	+0.07	% FSR	
Gain Error	-0.07	±0.015	+0.07	% FSR	
Full-Scale Error	-0.06	±0.015	+0.06	% FSR	
OUTPUT CHARACTERISTICS ²					
Headroom		1	2.2	V	
Footroom		0.7	1.4	V	Bipolar output ranges
Output Voltage Drift vs. Time		20		ppm FSR	Drift after 1000 hours, $\frac{3}{4}$ scale output, $T_J = 150$ °C, $AV_{SS} = -15 \text{ V}$
Short-Circuit Current	12/6	16/8		mA	Programmable by user, defaults to 16 mA typical level
Load	1			kΩ	For specified performance

Parameter ¹	Min	Тур	Max	Unit	Test Conditions/Comments
Capacitive Load Stability			10	nF	
			2	μF	External compensation capacitor of 220 pF connected
DC Output Impedance		0.06		Ω	
DC PSRR		50		μV/V	
DC Crosstalk		24		μV	
CURRENT OUTPUT					
Output Current Ranges	0		24	mA	
	0		20	mA	
	4		20	mA	
Resolution	16			Bits	
ACCURACY (EXTERNAL R _{SET})					Assumes ideal resistor
Total Unadjusted Error (TUE)	-0.05	±0.009	+0.05	% FSR	
TUE Long-Term Stability		100		ppm FSR	Drift after 1000 hours, T _J = 150°C
Relative Accuracy (INL)	-0.006		+0.006	% FSR	, -
Differential Nonlinearity (DNL)	-1		+1	LSB	Guaranteed monotonic
Offset Error	-0.05	±0.005	+0.05	% FSR	
Offset Error Drift ²		±4		ppm FSR/°C	
Gain Error	-0.05	±0.004	+0.05	% FSR	
Gain TC ²	0.05	±3	. 0.00	ppm FSR/°C	
Full-Scale Error	-0.05	±0.008	+0.05	% FSR	
Full-Scale TC ²	0.05	±5	10.03	ppm FSR/°C	
DC Crosstalk		0.0005		% FSR	External R _{SET}
ACCURACY (INTERNAL R _{SET})		0.0003		701311	External rises
Total Unadjusted Error (TUE) ^{4, 5}	-0.14		+0.14	% FSR	
Total offaujusted Effor (TOE)	-0.14	±0.009	+0.14	% FSR	T _A = 25°C
TUE Long-Term Stability	-0.11	180	TU.11	ppm FSR	Drift after 1000 hours, $T_J = 150^{\circ}C$
Relative Accuracy (INL)	-0.006	160	+0.006	% FSR	Diff after 1000 flours, 1) = 150 C
Relative Accuracy (INL)	-0.006		+0.004	% FSR	T _A = 25°C
•	-0.00 4 -1		+0.004 +1	LSB	
Differential Nonlinearity (DNL)					Guaranteed monotonic
Offset Error ^{4, 5}	-0.05	. 0 007	+0.05	% FSR % FSR	T 25%
O((-1) F D :(6)	-0.04	±0.007	+0.04		$T_A = 25$ °C
Offset Error Drift ²	0.13	±6	. 0.40	ppm FSR/°C	
Gain Error	-0.12		+0.12	% FSR	T 0505
c3	-0.06	±0.002	+0.06	% FSR	$T_A = 25$ °C
Gain TC ²	0.4.4	±9	. 0.4.4	ppm FSR/°C	
Full-Scale Error ^{4, 5}	-0.14		+0.14	% FSR	T 0705
_ ,, _ ,	-0.1	±0.007	+0.1	% FSR	T _A = 25°C
Full-Scale TC ²		±14		ppm FSR/°C	
DC Crosstalk⁵		-0.011		% FSR	Internal R _{SET}
OUTPUT CHARACTERISTICS ²					
Current Loop Compliance Voltage		V _{BOOST_x} –	V _{BOOST_x} -	V	
0		2.4	2.7		2.6.6.4001
Output Current Drift vs. Time					Drift after 1000 hours, ¾ scale output, T _J = 150°C
		90		ppm FSR	External R _{SET}
		140		ppm FSR	Internal R _{SET}
Resistive Load			1000	Ω	The dc-to-dc converter has been characterized with
					a maximum load of 1 k Ω , chosen such that compliance is not exceeded; see Figure 53 and DC DC
					ance is not exceeded; see Figure 53 and DC-DC MaxV bits in Table 25
Output Impedance		100		ΜΩ	Many Dits III Table 25
DC PSRR		0.02	1	μΑ/V	
טכראחו		0.02	1	μΑ/ ν	

Parameter ¹	Min	Тур	Max	Unit	Test Conditions/Comments
REFERENCE INPUT/OUTPUT					
Reference Input ²					
Reference Input Voltage	4.95	5	5.05	V	For specified performance
DC Input Impedance	45	150		ΜΩ	
Reference Output					
Output Voltage	4.995	5	5.005	V	T _A = 25°C
Reference TC ²	-10	±5	+10	ppm/°C	
Output Noise (0.1 Hz to 10 Hz) ²		7		μV p-p	
Noise Spectral Density ²		100		nV/√Hz	At 10 kHz
Output Voltage Drift vs. Time ²		180		ppm	Drift after 1000 hours, T _J = 150°C
Capacitive Load ²		1000		nF	
Load Current		9		mA	See Figure 64
Short-Circuit Current		10		mA	
Line Regulation ²		3		ppm/V	See Figure 65
Load Regulation ²		95		ppm/mA	See Figure 64
Thermal Hysteresis ²		160		ppm	First temperature cycle
memarry steresis		5		ppm	Second temperature cycle
DC-TO-DC				ppiii	Second temperature cycle
Switch					
Switch On Resistance		0.425		Ω	
Switch Leakage Current		10		nA	
Peak Current Limit		0.8		A	
Oscillator		0.0			
Oscillator Frequency	11.5	13	14.5	MHz	This oscillator is divided down to give the dc-to-dc
Oscillator Frequency	11.5	13	14.5	IVII IZ	converter switching frequency
Maximum Duty Cycle		89.6		%	At 410 kHz dc-to-dc switching frequency
DIGITAL INPUTS ²				1,0	JEDEC compliant
V _{IH} , Input High Voltage	2			V	3EBEC COMPILATE
V _{IL} , Input Low Voltage	_		0.8	V	
Input Current	-1		+1	μA	Per pin
Pin Capacitance		2.6		pF	Per pin
DIGITAL OUTPUTS ²		2.0		Pi	T CT pill
SDO, ALERT					
V _{oL} , Output Low Voltage			0.4	V	Sinking 200 μA
V _{OH} , Output High Voltage	DVDD - 0.5		0.4	V	Sourcing 200 μA
High Impedance Leakage	-1		+1	μA	Sourcing 200 μA
Current	-		TI	μΑ	
High Impedance Output		2.5		pF	
Capacitance		2.3		β.	
FAULT					
V _{OL} , Output Low Voltage			0.4	V	10 kΩ pull-up resistor to DV _{DD}
V _{OL} , Output Low Voltage		0.6		V	At 2.5 mA
V _{OH} , Output High Voltage	3.6			V	10 kΩ pull-up resistor to DV _{DD}
POWER REQUIREMENTS	2.0			+	
AV _{DD}	9		33	V	
AV _{SS}	-26.4		-10.8/0	V	
VA22					
DV_{DD}	2.7		5.5	V	

Parameter ¹	Min	Тур	Max	Unit	Test Conditions/Comments
Al _{DD}		8.6	10.5	mA	Voltage output mode on all channels, output unloaded, over supplies
		7	7.5	mA	Current output mode on all channels
Alss	-11	-8.8		mA	Voltage output mode on all channels, output unloaded, over supplies
	-1.7			mA	Current output mode on all channels
DI_CC		9.2	11	mA	$V_{IH} = DV_{DD}, V_{IL} = DGND$, internal oscillator running, over supplies
Alcc			1	mA	Output unloaded, over supplies
Івооsт			2.7	mA	Per channel, voltage output mode, output unloaded, over supplies
I _{BOOST} 6			1	mA	Per channel, current output mode, 0 mA output
Power Dissipation		173		mW	$AV_{DD} = +15 \text{ V}$, $AV_{SS} = -15 \text{ V}$, dc-to-dc converter enable, current output mode, outputs disabled

 $^{^{1}}$ Temperature range: -40° C to $+105^{\circ}$ C; typical at $+25^{\circ}$ C.

AC PERFORMANCE CHARACTERISTICS

 $AV_{DD} = V_{BOOST_x} = 15 \text{ V}; \ AV_{SS} = -15 \text{ V}; \ DV_{DD} = 2.7 \text{ V} \ to 5.5 \text{ V}; \ AV_{CC} = 4.5 \text{ V} \ to 5.5 \text{ V}; \ dc\text{-to-dc} \ converter \ disabled; \ AGND = DGND = GNDSW_x = 0 \text{ V}; \ REFIN = 5 \text{ V}; \ voltage \ outputs: \ R_L = 2 \text{ k}\Omega, \ C_L = 220 \text{ pF}; \ current \ outputs: \ R_L = 300 \ \Omega; \ all \ specifications \ T_{MIN} \ to \ T_{MAX}, \ unless \ otherwise \ noted.$

Table 2.

Parameter ¹	Min	Тур	Max	Unit	Test Conditions/Comments
DYNAMIC PERFORMANCE					
Voltage Output					
Output Voltage Settling Time		11		μs	5 V step to ±0.03% FSR, 0 V to 5 V range
			18	μs	10 V step to ±0.03% FSR, 0 V to 10 V range
			13	μs	100 mV step to 1 LSB (16-bit LSB), 0 V to 10 V range
Slew Rate		1.9		V/µs	0 V to 10 V range
Power-On Glitch Energy		150		nV-sec	
Digital-to-Analog Glitch Energy		6		nV-sec	
Glitch Impulse Peak Amplitude		25		mV	
Digital Feedthrough		1		nV-sec	
DAC to DAC Crosstalk		2		nV-sec	0 V to 10 V range
Output Noise (0.1 Hz to 10 Hz Bandwidth)		0.15		LSB p-p	16-bit LSB, 0 V to 10 V range
Output Noise Spectral Density		150		nV/√Hz	Measured at 10 kHz, midscale output, 0 V to 10 V range
AC PSRR		83		dB	200 mV 50 Hz/60 Hz sine wave superimposed on power supply voltage
Current Output					
Output Current Settling Time		15		μs	To 0.1% FSR (0 mA to 24 mA)
		See test conditions/ comments		ms	See Figure 49, Figure 50, and Figure 51
Output Noise (0.1 Hz to 10 Hz Bandwidth)		0.15		LSB p-p	16-bit LSB, 0 mA to 24 mA range
Output Noise Spectral Density		0.5		nA/√Hz	Measured at 10 kHz, midscale output, 0 mA to 24 mA range

¹ Guaranteed by design and characterization; not production tested.

² Guaranteed by design and characterization; not production tested.

³ For voltage output ranges in unipolar supply mode, the INL and TUE are measured beginning from Code 4096.

⁴ For current outputs with internal R_{SET}, the offset, full-scale, and TUE measurements exclude dc crosstalk. The measurements are made with all four channels enabled loaded with the same code.

⁵ See the Current Output Mode with Internal R_{SET} section for more explanation of the dc crosstalk.

⁶ Efficiency plots in Figure 55, Figure 56, Figure 57, and Figure 58 include the I_{BOOST} quiescent current

TIMING CHARACTERISTICS

 $AV_{DD} = V_{BOOST_x} = 15 \text{ V}; \ AV_{SS} = -15 \text{ V}; \ DV_{DD} = 2.7 \text{ V to } 5.5 \text{ V}; \ AV_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; \ dc\text{-to-dc converter disabled}; \ AGND = DGND = 100 \text{ Converter disabled}; \ AGND = 100 \text{ Conver$ $GNDSW_x = 0 \text{ V}$; REFIN = 5 V; voltage outputs: $R_L = 1 \text{ k}\Omega$, $C_L = 220 \text{ pF}$; current outputs: $R_L = 300 \Omega$; all specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 3.

Parameter ^{1, 2, 3}	Limit at T _{MIN} , T _{MAX}	Unit	Description
t ₁	33	ns min	SCLK cycle time
t_2	13	ns min	SCLK high time
t_3	13	ns min	SCLK low time
t ₄	13	ns min	SYNC falling edge to SCLK falling edge setup time
t ₅	13	ns min	24 th /32 nd SCLK falling edge to SYNC rising edge (see Figure 78)
t ₆	198	ns min	SYNC high time
t ₇	5	ns min	Data setup time
t ₈	5	ns min	Data hold time
t ₉	20	μs min	SYNC rising edge to LDAC falling edge (all DACs updated or any channel has digital slew rate control enabled)
	5	μs min	SYNC rising edge to LDAC falling edge (single DAC updated)
t ₁₀	10	ns min	LDAC pulse width low
t ₁₁	500	ns max	LDAC falling edge to DAC output response time
t ₁₂	See the AC Performance Characteristics section	μs max	DAC output settling time
t ₁₃	10	ns min	CLEAR high time
t ₁₄	5	μs max	CLEAR activation time
t ₁₅	40	ns max	SCLK rising edge to SDO valid
t ₁₆	21	μs min	$\overline{\text{SYNC}}$ rising edge to DAC output response time ($\overline{\text{LDAC}} = 0$) (all DACs updated)
	5	μs min	$\overline{\text{SYNC}}$ rising edge to DAC output response time ($\overline{\text{LDAC}} = 0$) (single DAC updated)
t ₁₇	500	ns min	LDAC falling edge to SYNC rising edge
t ₁₈	800	ns min	RESET pulse width
t_{19}^4	20	μs min	SYNC high to next SYNC low (digital slew rate control enabled) (all DACs updated)
	5	μs min	SYNC high to next SYNC low (digital slew rate control disabled) (single DAC updated)

 $^{^{\}mbox{\tiny 1}}$ Guaranteed by design and characterization; not production tested.

² All input signals are specified with $t_R = t_F = 5$ ns (10% to 90% of DV_{DD}) and timed from a voltage level of 1.2 V.

³ See Figure 3, Figure 4, Figure 5, and Figure 6.
⁴ This specification applies if LDAC is held low during the write cycle; otherwise, see t₉.

Timing Diagrams

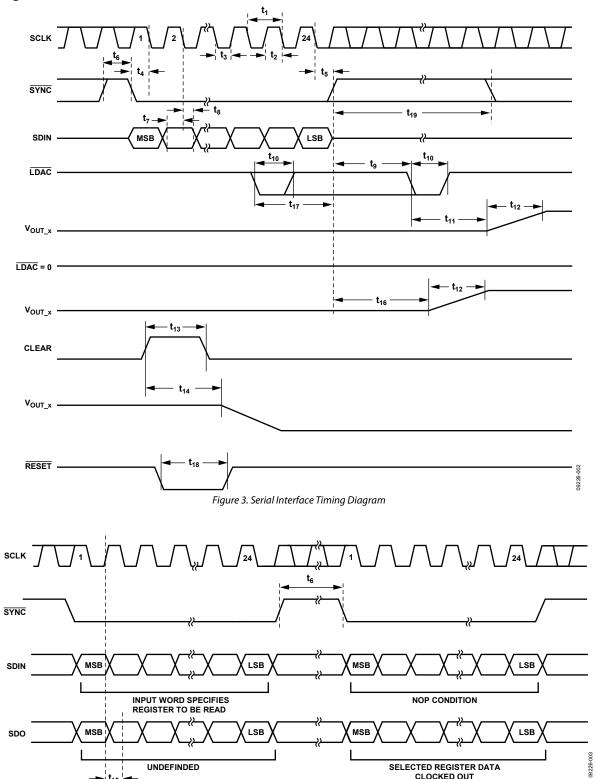


Figure 4. Readback Timing Diagram

UNDEFINDED

SELECTED REGISTER DATA CLOCKED OUT

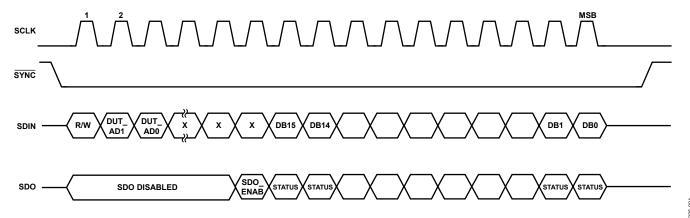


Figure 5. Status Readback During Write

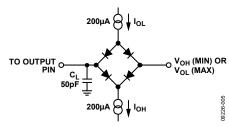


Figure 6. Load Circuit for SDO Timing Diagram

ABSOLUTE MAXIMUM RATINGS

 T_A = 25°C, unless otherwise noted. Transient currents of up to 100 mA do not cause SCR latch-up.

Table 4.

1 able 4.	
Parameter	Rating
AV _{DD} , V _{BOOST_x} to AGND, DGND	−0.3 V to +33 V
AV _{ss} to AGND, DGND	+0.3 V to −28 V
AV_{DD} to AV_{SS}	−0.3 V to +60 V
AV _{cc} to AGND	−0.3 V to +7 V
DV _{DD} to DGND	−0.3 V to +7 V
Digital Inputs to DGND	-0.3 V to DV _{DD} + 0.3 V or +7 V (whichever is less)
Digital Outputs to DGND	$-0.3 \text{ V to DV}_{DD} + 0.3 \text{ V or } +7 \text{ V}$ (whichever is less)
REFIN, REFOUT to AGND	$-0.3 \text{ V to AV}_{DD} + 0.3 \text{ V or } +7 \text{ V}$ (whichever is less)
V_{OUT_x} to AGND	AV _{SS} to V _{BOOST_x} or 33 V if using the dc-to-dc circuitry
$+V_{SENSE_x}$ to AGND	AV _{SS} to V _{BOOST_x} or 33 V if using the dc-to-dc circuitry
I_{OUT_x} to AGND	AV_{SS} to V_{BOOST_x} or 33 V if using the dc-to-dc circuitry
SW _x to AGND	−0.3 to +33 V
AGND, GNDSW _x to DGND	−0.3 V to +0.3 V
Operating Temperature Range (T _A)	
Industrial ¹	−40°C to +105°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature (T _J max)	125°C
64-Lead LFCSP	
θ_{JA} Thermal Impedance ²	20°C/W
Power Dissipation	(T _J max – T _A)/θ _{JA}
Lead Temperature	JEDEC industry standard
Soldering	J-STD-020

 $^{^{\}rm 1}$ Power dissipated on chip must be derated to keep the junction temperature below 125°C.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

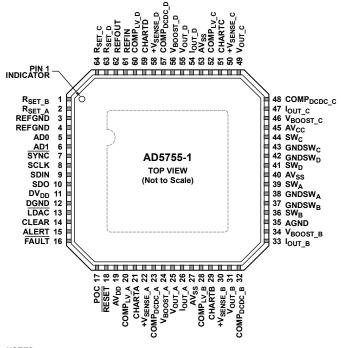
ESD CAUTION



ESD (electrostatic discharge) sensitive device.Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

 $^{^{\}rm 2}$ Based on a JEDEC 4-layer test board.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



NOTES

1. THE EXPOSED PAD SHOULD BE CONNECTED TO THE POTENTIAL OF THE AV_{SS} PIN, OR, ALTERNATIVELY, IT CAN BE LEFT ELECTRICALLY UNCONNECTED. IT IS RECOMMENDED THAT THE PAD BE THERMALLY CONNECTED TO A COPPER PLANE FOR ENHANCED THERMAL PERFORMANCE.

Figure 7. Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	R _{SET_B}	An external, precision, low drift 15 k Ω current setting resistor can be connected to this pin to improve the l_{OUT_B} temperature drift performance. See the Device Features section.
2	R _{SET_A}	An external, precision, low drift 15 k Ω current setting resistor can be connected to this pin to improve the l_{OUT_A} temperature drift performance. See the Device Features section.
3, 4	REFGND	Ground Reference Point for Internal Reference.
5	AD0	Address Decode for the Device Under Test (DUT) on the Board.
6	AD1	Address Decode for the DUT on the Board.
7	SYNC	Active Low Input. This is the frame synchronization signal for the serial interface. While SYNC is low, data is transferred in on the falling edge of SCLK.
8	SCLK	Serial Clock Input. Data is clocked into the input shift register on the rising edge of SCLK. This operates at clock speeds of up to 30 MHz.
9	SDIN	Serial Data Input. Data must be valid on the falling edge of SCLK.
10	SDO	Serial Data Output. Used to clock data from the serial register in readback mode. See Figure 4 and Figure 5.
11	DV _{DD}	Digital Supply. The voltage range is from 2.7 V to 5.5 V.
12	DGND	Digital Ground.
13	LDAC	Load DAC, Active Low Input. This is used to update the DAC register and consequently the DAC outputs. When tied permanently low, the addressed DAC data register is updated on the rising edge of SYNC. If LDAC is held high during the write cycle, the DAC input register is updated, but the DAC output update only takes place at the falling edge of LDAC (see Figure 3). Using this mode, all analog outputs can be updated simultaneously. The LDAC pin must not be left unconnected.
14	CLEAR	Active High, Edge Sensitive Input. Asserting this pin sets the output current and voltage to the preprogrammed clear code bit setting. Only channels enabled to be cleared are cleared. See the Device Features section for mor information. When CLEAR is active, the DAC output register cannot be written to.

Pin No.	Mnemonic	Description
15	ALERT	Active High Output. This pin is asserted when there has been no SPI activity on the interface pins for a predetermined time. See the Device Features section for more information.
16	FAULT	Active Low Output. This pin is asserted low when an open circuit in current mode is detected, a short circuit in voltage mode is detected, a PEC error is detected, or an overtemperature is detected (see the Device Features section). Open-drain output.
17	POC	Power-On Condition. This pin determines the power-on condition and is read during power-on or, alternatively, after a device reset. If POC = 0, the device is powered up with the voltage and current channels in tristate mode. If POC = 1, the device is powered up with a 30 k Ω pull-down resistor to ground on the voltage output channel, and the current channel is in tristate mode.
18	RESET	Hardware Reset, Active Low Input.
19	AV _{DD}	Positive Analog Supply. The voltage range is from 9 V to 33 V.
20	COMP _{LV_A}	Optional Compensation Capacitor Connection for V_{OUT_A} Output Buffer. Connecting a 220 pF capacitor between this pin and the V_{OUT_A} pin allows the voltage output to drive up to 2 μ F. Note that the addition of this capacitor reduces the bandwidth of the output amplifier, increasing the settling time.
21	CHARTA	HART Input Connection for DAC Channel A.
22	+V _{SENSE_A}	Sense Connection for the Positive Voltage Output Load Connection for Vout_A.
23	COMP _{DCDC_A}	DC-to-DC Compensation Capacitor. Connect a 10 nF capacitor from this pin to ground. Used to regulate the feedback loop of the Channel A dc-to-dc converter. Alternatively, if using an external compensation resistor, place a resistor in series with a capacitor to ground from this pin (see the DC-to-DC Converter Compensation Capacitors and the Alcc Supply Requirements—Slewing sections in the Device Features section for more information).
24	V _{BOOST_A}	Supply for Channel A Current Output Stage (see Figure 73). This is also the supply for the $V_{OUT_{-X}}$ stage, which is regulated to 15 V by the dc-to-dc converter. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
25	V _{OUT_A}	Buffered Analog Output Voltage for DAC Channel A.
26	I _{OUT_A}	Current Output Pin for DAC Channel A.
27	AVss	Negative Analog Supply. Voltage range is from -10.8 V to -26.4 V.
28	COMP _{LV_B}	Optional Compensation Capacitor Connection for V_{OUT_B} Output Buffer. Connecting a 220 pF capacitor between this pin and the V_{OUT_B} pin allows the voltage output to drive up to 2 μ F. Note that the addition of this capacitor reduces the bandwidth of the output amplifier, increasing the settling time.
29	CHARTB	HART Input Connection for DAC Channel B.
30	+V _{SENSE_B}	Sense Connection for the Positive Voltage Output Load Connection for Vout_B.
31	V_{OUT_B}	Buffered Analog Output Voltage for DAC Channel B.
32	COMP _{DCDC_B}	DC-to-DC Compensation Capacitor. Connect a 10 nF capacitor from this pin to ground. Used to regulate the feedback loop of the Channel B dc-to-dc converter. Alternatively, if using an external compensation resistor, place a resistor in series with a capacitor to ground from this pin (see the DC-to-DC Converter Compensation Capacitors and Alcc Supply Requirements—Slewing sections in the Device Features section for more information).
33	І оит_в	Current Output Pin for DAC Channel B.
34	V _{BOOST_B}	Supply for Channel B Current Output Stage (see Figure 73). This is also the supply for the $V_{OUT_{-}x}$ stage, which is regulated to 15 V by the dc-to-dc converter. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
35	AGND	Ground Reference Point for Analog Circuitry. This must be connected to 0 V.
36	SW _B	Switching Output for Channel B DC-to-DC Circuitry. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
37	GNDSW _B	Ground Connection for DC-to-DC Switching Circuit. This pin should always be connected to ground.
38	GNDSW _A	Ground Connection for DC-to-DC Switching Circuit. This pin should always be connected to ground.
39	SW _A	Switching Output for Channel A DC-to-DC Circuitry. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
40	AVss	Negative Analog Supply Pin. The voltage range is from -10.8 V to -26.4 V. This pin can be connected to 0 V if using the device in unipolar supply mode.
41	SW _D	Switching Output for Channel D DC-DC Circuitry. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
42	GNDSW _D	Ground Connections for DC-to-DC Switching Circuit. This pin should always be connected to ground.
43	$GNDSW_C$	Ground Connections for DC-to-DC Switching Circuit. This pin should always be connected to ground.
44	SWc	Switching Output for Channel C DC-to-DC Circuitry. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
45	AV _{CC}	Supply for DC-to-DC Circuitry.

Pin No.	Mnemonic	Description
46	V _{BOOST_C}	Supply for Channel C Current Output Stage (see Figure 73). This is also the supply for the V _{OUT_x} stage, which is regulated to 15 V by the dc-to-dc converter. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
47	I _{OUT_C}	Current Output Pin for DAC Channel C.
48	COMP _{DCDC_C}	DC-to-DC Compensation Capacitor. Connect a 10 nF capacitor from this pin to ground. Used to regulate the feedback loop of the Channel C dc-to-dc converter. Alternatively, if using an external compensation resistor, place a resistor in series with a capacitor to ground from this pin (see the DC-to-DC Converter Compensation Capacitors and Al _{CC} Supply Requirements—Slewing sections in the Device Features section for more information).
49	V _{OUT_C}	Buffered Analog Output Voltage for DAC Channel C.
50	+V _{SENSE_C}	Sense Connection for the Positive Voltage Output Load Connection for V _{OUT_C} .
51	CHARTC	HART Input Connection for DAC Channel C.
52	COMP _{LV_C}	Optional Compensation Capacitor Connection for V_{OUT_C} Output Buffer. Connecting a 220 pF capacitor between this pin and the V_{OUT_C} pin allows the voltage output to drive up to 2 µF. Note that the addition of this capacitor reduces the bandwidth of the output amplifier, increasing the settling time.
53	AV _{SS}	Negative Analog Supply Pin.
54	lout_d	Current Output Pin for DAC Channel D.
55	V _{OUT_D}	Buffered Analog Output Voltage for DAC Channel D.
56	V _{BOOST_D}	Supply for Channel D Current Output Stage (see Figure 73). This is also the supply for the V _{OUT_X} stage, which is regulated to 15 V by the dc-to-dc converter. To use the dc-to-dc feature of the device, connect as shown in Figure 80.
57	COMP _{DCDC_D}	DC-to-DC Compensation Capacitor. Connect a 10 nF capacitor from this pin to ground. Used to regulate the feedback loop of the Channel D dc-to-dc converter. Alternatively, if using an external compensation resistor, place a resistor in series with a capacitor to ground from this pin (see the DC-to-DC Converter Compensation Capacitors and Alcc Supply Requirements—Slewing sections in the Device Features section for more information).
58	$+V_{SENSE_D}$	Sense Connection for the Positive Voltage Output Load Connection for V _{OUT_D} .
59	CHARTD	HART Input Connection for DAC Channel D
60	COMP _{LV_D}	Optional Compensation Capacitor Connection for V_{OUT_D} Output Buffer. Connecting a 220 pF capacitor between this pin and the V_{OUT_D} pin allows the voltage output to drive up to 2 μ F. Note that the addition of this capacitor reduces the bandwidth of the output amplifier, increasing the settling time.
61	REFIN	External Reference Voltage Input.
62	REFOUT	Internal Reference Voltage Output. It is recommended to place a 0.1 µF capacitor between REFOUT and REFGND.
63	R _{SET_D}	An external, precision, low drift 15 k Ω current setting resistor can be connected to this pin to improve the l_{OUT_D} temperature drift performance. See the Device Features section.
64	R _{SET_C}	An external, precision, low drift 15 k Ω current setting resistor can be connected to this pin to improve the l_{OUT_C} temperature drift performance. See the Device Features section.
	EPAD	Exposed Pad. This exposed pad should be connected to the potential of the AV _{SS} pin, or, alternatively, it can be left electrically unconnected. It is recommended that the pad be thermally connected to a copper plane for enhanced thermal performance.

TYPICAL PERFORMANCE CHARACTERISTICS

VOLTAGE OUTPUTS

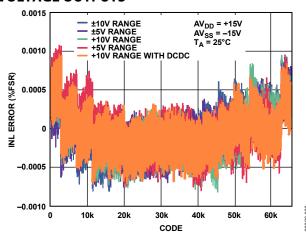


Figure 8. Integral Nonlinearity Error vs. DAC Code

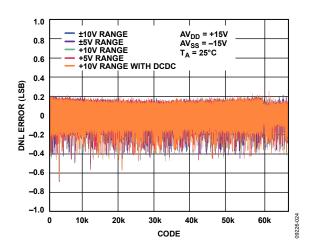


Figure 9. Differential Nonlinearity Error vs. DAC Code

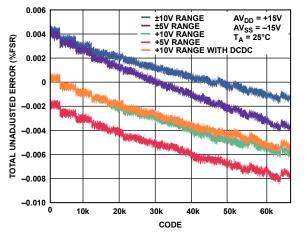


Figure 10. Total Unadjusted Error vs. DAC Code

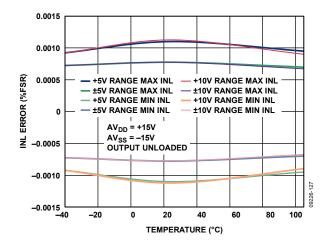


Figure 11. Integral Nonlinearity Error vs. Temperature

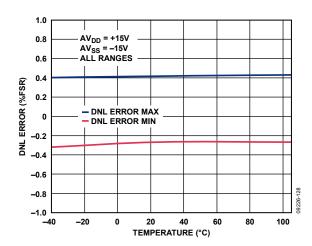


Figure 12. Differential Nonlinearity Error vs. Temperature

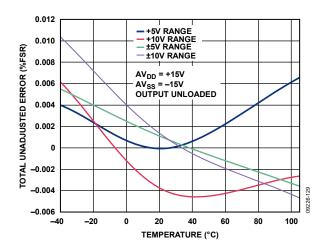


Figure 13. Total Unadjusted Error vs. Temperature

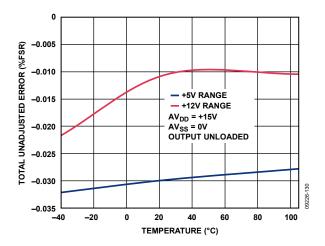


Figure 14. Total Unadjusted Error vs. Temperature, Single Supply

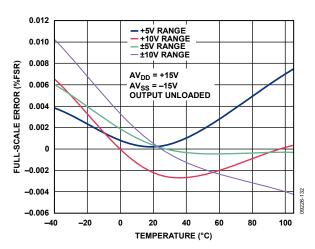


Figure 15. Full-Scale Error vs. Temperature

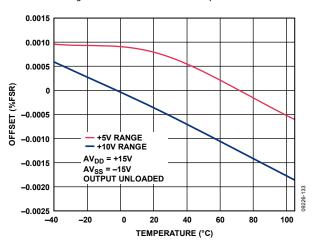


Figure 16. Offset Error vs. Temperature

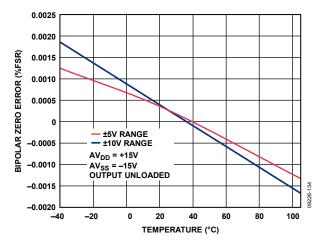


Figure 17. Bipolar Zero Error vs. Temperature

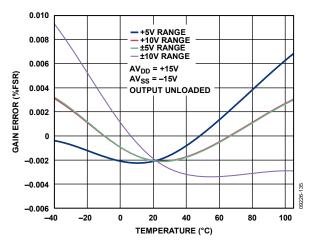


Figure 18. Gain Error vs. Temperature

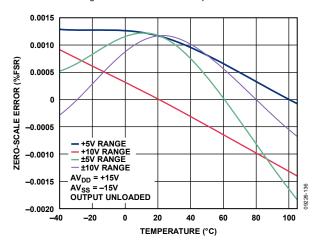


Figure 19. Zero-Scale Error vs. Temperature

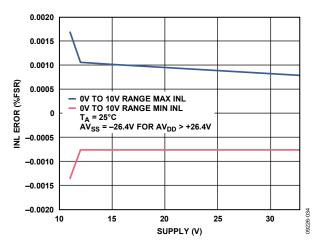


Figure 20. Integral Nonlinearity Error vs. AVDD/AVSS

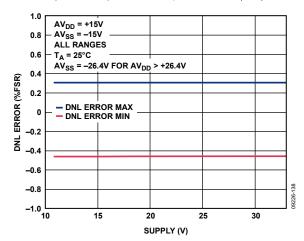


Figure 21. Differential Nonlinearity Error vs. AVDD/AVSS

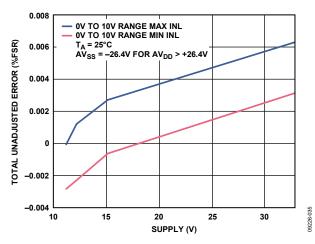


Figure 22. Total Unadjusted Error vs. AVDD/AVSS

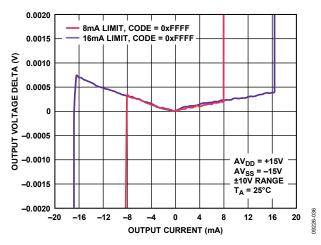


Figure 23. Source and Sink Capability of Output Amplifier

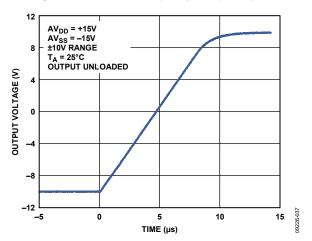


Figure 24. Full-Scale Positive Step

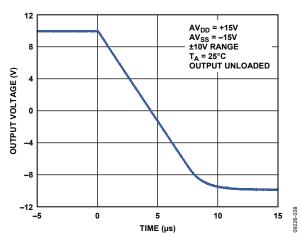


Figure 25. Full-Scale Negative Step

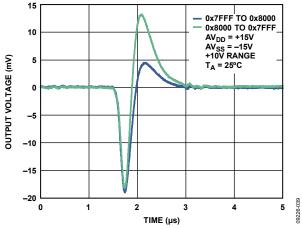


Figure 26. Digital-to-Analog Glitch

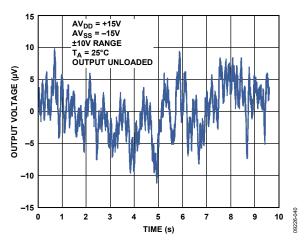


Figure 27. Peak-to-Peak Noise (0.1 Hz to 10 Hz Bandwidth)

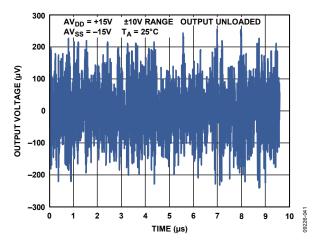


Figure 28. Peak-to-Peak Noise (100 kHz Bandwidth)

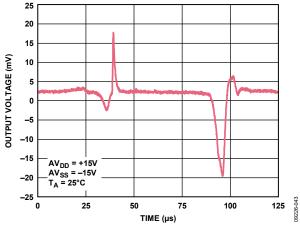


Figure 29. V_{OUT_x} vs. Time on Power-Up

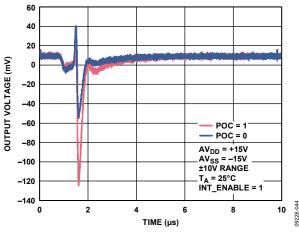


Figure 30. V_{OUT_x} vs. Time on Output Enable

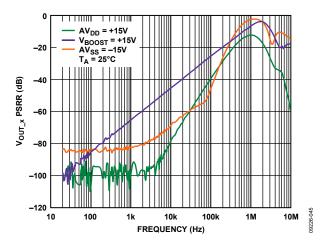


Figure 31. V_{OUT_x} PSRR vs. Frequency

CURRENT OUTPUTS

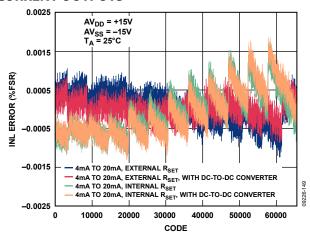


Figure 32. Integral Nonlinearity vs. Code

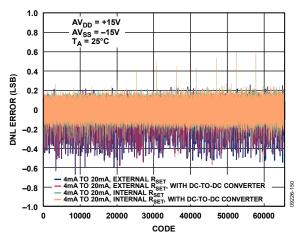


Figure 33. Differential Nonlinearity vs. Code

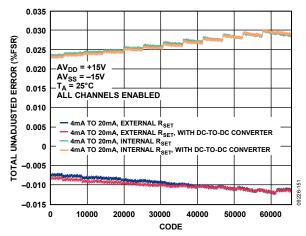


Figure 34. Total Unadjusted Error vs. Code

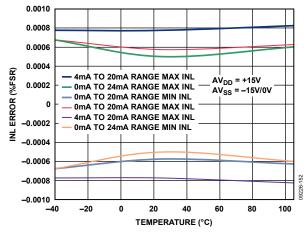


Figure 35. Integral Nonlinearity vs. Temperature, Internal RSET

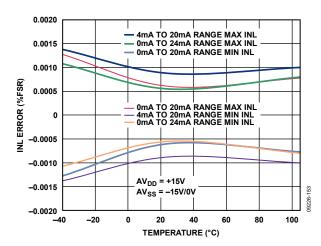


Figure 36. Integral Nonlinearity vs. Temperature, External R_{SET}

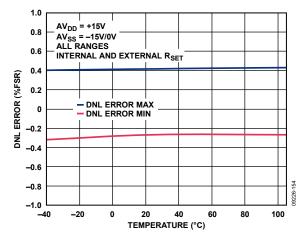


Figure 37. Differential Nonlinearity vs. Temperature

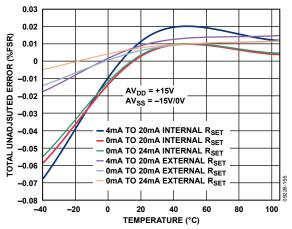


Figure 38. Total Unadjusted Error vs. Temperature

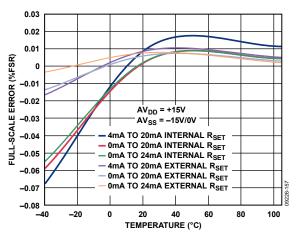


Figure 39. Full Scale Error vs. Temperature

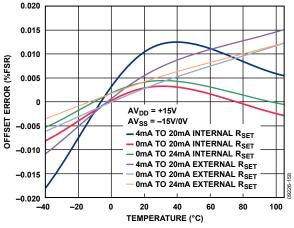


Figure 40. Offset Error vs. Temperature

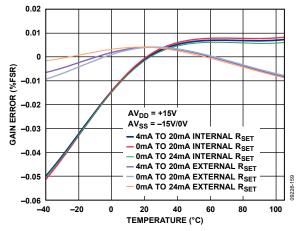


Figure 41. Gain Error vs. Temperature

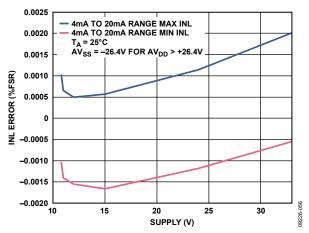


Figure 42. Integral Nonlinearity Error vs. AV_{DD}/|AV_{SS}|, Over Supply, External R_{SET}

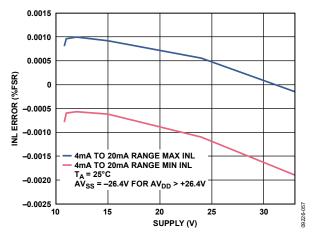


Figure 43. Integral Nonlinearity Error vs. AV_{DD}/|AV_{SS}|, Over Supply, Internal R_{SET}

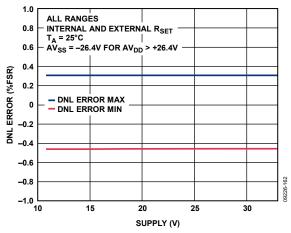


Figure 44. Differential Nonlinearity Error vs. AVDD

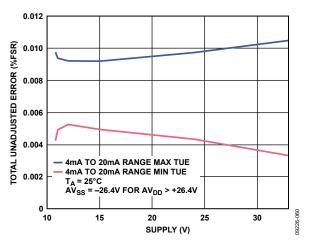


Figure 45. Total Unadjusted Error vs. AVDD, External RSET

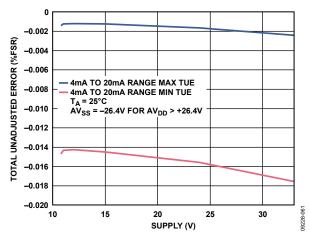


Figure 46. Total Unadjusted Error vs. AVDD, Internal RSET

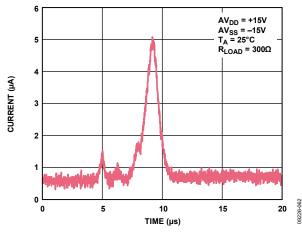


Figure 47. Output Current vs. Time on Power-Up

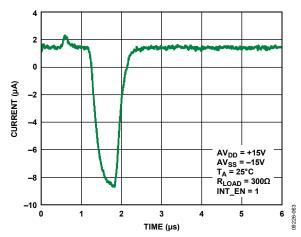


Figure 48. Output Current vs. Time on Output Enable

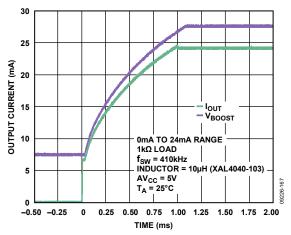


Figure 49. Output Current and V_{BOOST_x} Settling Time with DC-to-DC Converter (See Figure 80)

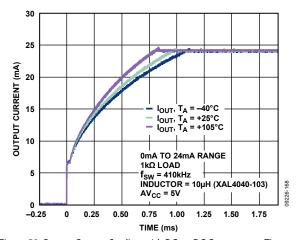


Figure 50. Output Current Settling with DC-to-DC Converter vs. Time and Temperature (See Figure 80)

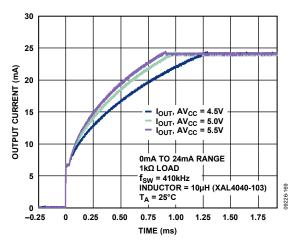


Figure 51. Output Current Settling with DC-to-DC Converter vs. Time and AV_{CC} (See Figure 80)

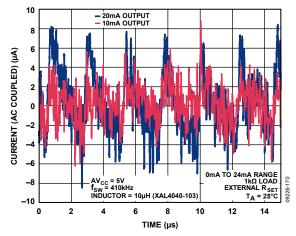


Figure 52. Output Current vs. Time with DC-to-DC Converter (See Figure 80)

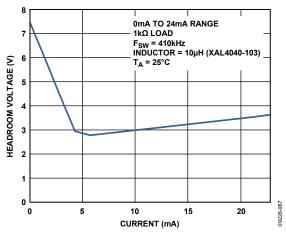


Figure 53. DC-to-DC Converter Headroom vs. Output Current (See Figure 80)

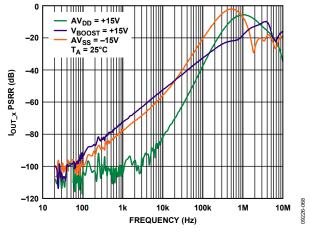


Figure 54. I_{OUT_x} PSRR vs. Frequency

DC-TO-DC BLOCK

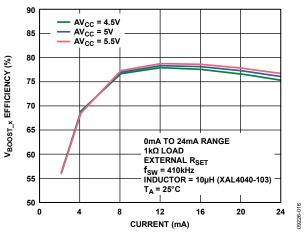


Figure 55. Efficiency at V_{BOOST_x} vs. Output Current (See Figure 80)

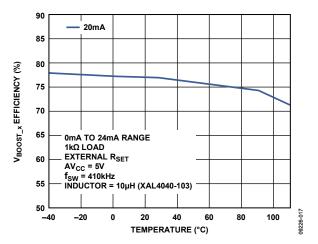


Figure 56. Efficiency at V_{BOOST_x} vs. Temperature (See Figure 80)

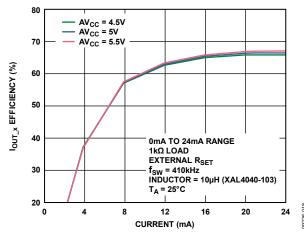


Figure 57. Output Efficiency vs. Output Current (See Figure 80)

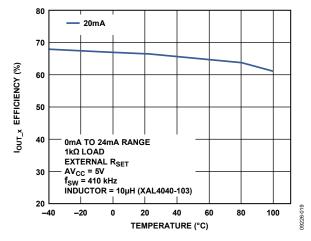


Figure 58. Output Efficiency vs. Temperature (See Figure 80)

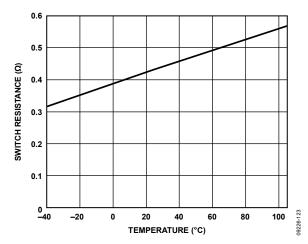


Figure 59. Switch Resistance vs. Temperature

REFERENCE

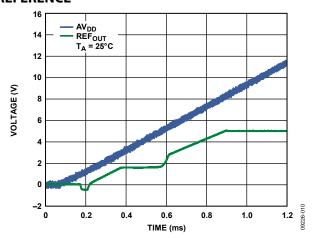


Figure 60. REFOUT Turn-On Transient

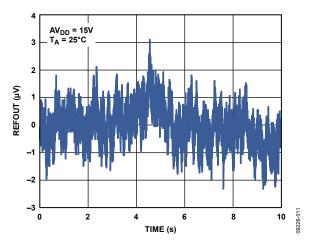


Figure 61. REFOUT Output Noise (0.1 Hz to 10 Hz Bandwidth)

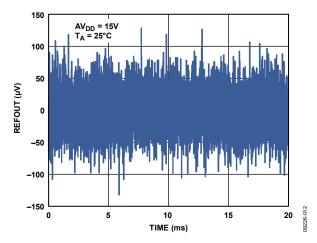


Figure 62. REFOUT Output Noise (100 kHz Bandwidth)

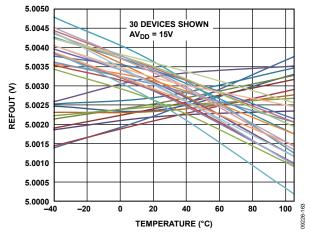


Figure 63. REFOUT vs. Temperature (When the AD5755-1 is soldered onto a PCB, the reference shifts due to thermal shock on the package. The average output voltage shift is -4 mV. Measurement of these parts after seven days shows that the outputs typically shift back 2 mV toward their initial values. This second shift is due to the relaxation of stress incurred during soldering.)

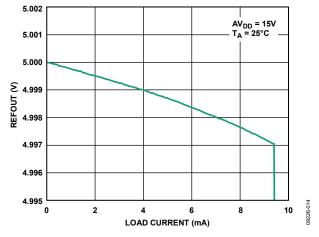


Figure 64. REFOUT vs. Load Current

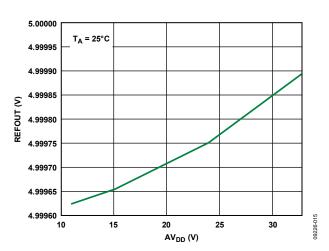


Figure 65. REFOUT vs. Supply

GENERAL

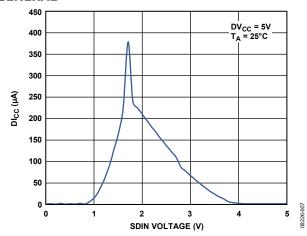


Figure 66. DIcc vs. Logic Input Voltage

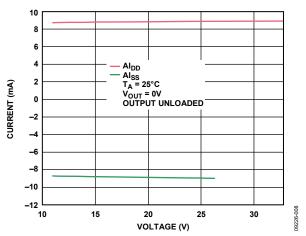
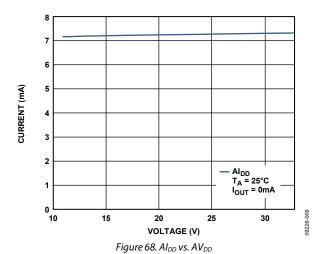


Figure 67. AI_{DD}/AI_{SS} vs. $AV_{DD}/|AV_{SS}|$



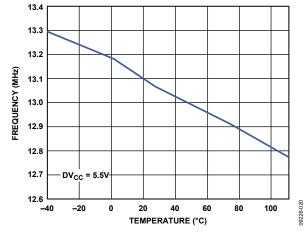


Figure 69. Internal Oscillator Frequency vs. Temperature

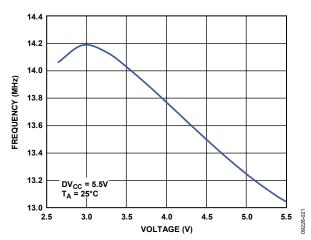


Figure 70. Internal Oscillator Frequency vs. DV_{CC} Supply Voltage

TERMINOLOGY

Relative Accuracy or Integral Nonlinearity (INL)

For the DAC, relative accuracy, or integral nonlinearity, is a measure of the maximum deviation, in LSBs, from the best fit line through the DAC transfer function. A typical INL vs. code plot is shown in Figure 8.

Differential Nonlinearity (DNL)

Differential nonlinearity (DNL) is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of ± 1 LSB maximum ensures monotonicity. This DAC is guaranteed monotonic by design. A typical DNL vs. code plot is shown in Figure 9.

Monotonicity

A DAC is monotonic if the output either increases or remains constant for increasing digital input code. The AD5755-1 is monotonic over its full operating temperature range.

Negative Full-Scale Error/Zero-Scale Error

Negative full-scale error is the error in the DAC output voltage when 0x0000 (straight binary coding) is loaded to the DAC register.

Zero-Scale TC

This is a measure of the change in zero-scale error with a change in temperature. Zero-scale error TC is expressed in ppm FSR/°C.

Bipolar Zero Error

Bipolar zero error is the deviation of the analog output from the ideal half-scale output of 0 V when the DAC register is loaded with 0x8000 (straight binary coding).

Bipolar Zero TC

Bipolar zero TC is a measure of the change in the bipolar zero error with a change in temperature. It is expressed in ppm FSR/°C.

Offset Error

In voltage output mode, offset error is the deviation of the analog output from the ideal quarter-scale output when in bipolar output ranges and the DAC register is loaded with 0x4000 (straight binary coding).

In current output mode, offset error is the deviation of the analog output from the ideal zero-scale output when all DAC registers are loaded with 0x0000.

Gain Error

This is a measure of the span error of the DAC. It is the deviation in slope of the DAC transfer characteristic from the ideal, expressed in % FSR.

Gain TC

This is a measure of the change in gain error with changes in temperature. Gain TC is expressed in ppm FSR/°C.

Full-Scale Error

Full-scale error is a measure of the output error when full-scale code is loaded to the DAC register. Ideally, the output should be full-scale – 1 LSB. Full-scale error is expressed in percent of full-scale range (% FSR).

Full-Scale TC

Full-scale TC is a measure of the change in full-scale error with changes in temperature and is expressed in ppm FSR/°C.

Total Unadjusted Error

Total unadjusted error (TUE) is a measure of the output error taking all the various errors into account, including INL error, offset error, gain error, temperature, and time. TUE is expressed in % FSR.

DC Crosstalk

This is the dc change in the output level of one DAC in response to a change in the output of another DAC. It is measured with a full-scale output change on one DAC while monitoring another DAC, which is at midscale.

Current Loop Compliance Voltage

The maximum voltage at the I_{OUT_x} pin for which the output current is equal to the programmed value.

Voltage Reference Thermal Hysteresis

Voltage reference thermal hysteresis is the difference in output voltage measured at +25°C compared to the output voltage measured at +25°C after cycling the temperature from +25°C to -40°C to +105°C and back to +25°C. The hysteresis is specified for the first and second temperature cycles and is expressed in ppm.

Output Voltage Settling Time

Output voltage settling time is the amount of time it takes for the output to settle to a specified level for a full-scale input change. A plot of settling time is shown in Figure 24, Figure 50, and Figure 51.

Slew Rate

The slew rate of a device is a limitation in the rate of change of the output voltage. The output slewing speed of a voltage-output digital-to-analog converter is usually limited by the slew rate of the amplifier used at its output. Slew rate is measured from 10% to 90% of the output signal and is given in $V/\mu s$.

Power-On Glitch Energy

Power-on glitch energy is the impulse injected into the analog output when the AD5755-1 is powered-on. It is specified as the area of the glitch in nV-sec. See Figure 29 and Figure 47.

Digital-to-Analog Glitch Impulse

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state, but the output voltage remains constant. It is normally specified as the area of the glitch in nV-sec and is measured when the digital input code is changed by 1 LSB at the major carry transition (~0x7FFF to 0x8000). See Figure 26.

Glitch Impulse Peak Amplitude

Glitch impulse peak amplitude is the peak amplitude of the impulse injected into the analog output when the input code in the DAC register changes state. It is specified as the amplitude of the glitch in mV and is measured when the digital input code is changed by 1 LSB at the major carry transition (~0x7FFF to 0x8000). See Figure 26.

Digital Feedthrough

Digital feedthrough is a measure of the impulse injected into the analog output of the DAC from the digital inputs of the DAC but is measured when the DAC output is not updated. It is specified in nV-sec and measured with a full-scale code change on the data bus.

DAC-to-DAC Crosstalk

DAC-to-DAC crosstalk is the glitch impulse transferred to the output of one DAC due to a digital code change and a subsequent output change of another DAC. This includes both digital and analog crosstalk. It is measured by loading one of the DACs with a full-scale code change (all 0s to all 1s and vice versa) with LDAC low and monitoring the output of another DAC. The energy of the glitch is expressed in nV-sec.

Power Supply Rejection Ratio (PSRR)

PSRR indicates how the output of the DAC is affected by changes in the power supply voltage.

Reference TC

Reference TC is a measure of the change in the reference output voltage with a change in temperature. It is expressed in ppm/°C.

Line Regulation

Line regulation is the change in reference output voltage due to a specified change in supply voltage. It is expressed in ppm/V.

Load Regulation

Load regulation is the change in reference output voltage due to a specified change in load current. It is expressed in ppm/mA.

DC-to-DC Converter Headroom

This is the difference between the voltage required at the current output and the voltage supplied by the dc-to-dc converter. See Figure 53.

Output Efficiency

$$\frac{\boldsymbol{I}_{\scriptscriptstyle OUT}^2 \times \boldsymbol{R}_{\scriptscriptstyle LOAD}}{\boldsymbol{A}\boldsymbol{V}_{\scriptscriptstyle CC} \times \boldsymbol{A}\boldsymbol{I}_{\scriptscriptstyle CC}}$$

This is defined as the power delivered to a channel's load vs. the power delivered to the channel's dc-to-dc input.

Efficiency at V_{BOOST_x}

$$\frac{I_{OUT} \times V_{BOOST_x}}{AV_{CC} \times AI_{CC}}$$

This is defined as the power delivered to a channel's V_{BOOST_x} supply vs. the power delivered to the channel's dc-to-dc input. The V_{BOOST_x} quiescent current is considered part of the dc-to-dc converter's losses.

THEORY OF OPERATION

The AD5755-1 is a quad, precision digital-to-current loop and voltage output converter designed to meet the requirements of industrial process control applications. It provides a high precision, fully integrated, low cost, single-chip solution for generating current loop and unipolar/bipolar voltage outputs. The current ranges available are 0 mA to 20 mA, 0 mA to 24 mA, and 4 mA to 20 mA. The voltage ranges available are 0 V to 5 V, ± 5 V, 0 V to 10 V, and ± 10 V. The current and voltage outputs are available on separate pins, and only one is active at any one time. The desired output configuration is user selectable via the DAC control register.

On-chip dynamic power control minimizes package power dissipation in current mode.

DAC ARCHITECTURE

The DAC core architecture of the AD5755-1 consists of two matched DAC sections. A simplified circuit diagram is shown in Figure 71. The four MSBs of the 16-bit data-word are decoded to drive 15 switches, E1 to E15. Each of these switches connects one of 15 matched resistors to either ground or the reference buffer output. The remaining 12 bits of the data-word drive Switch S0 to Switch S11 of a 12-bit voltage mode R-2R ladder network.

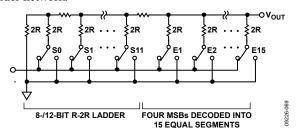
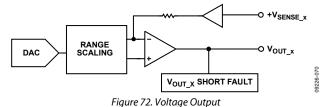


Figure 71. DAC Ladder Structure

The voltage output from the DAC core is either converted to a current (see Figure 73), which is then mirrored to the supply rail so that the application simply sees a current source output, or it is buffered and scaled to output a software selectable unipolar or bipolar voltage range (see Figure 72). Both the voltage and current outputs are supplied by $V_{\text{BOOST_x}}$. The current and voltage are output on separate pins and cannot be output simultaneously. A channel's current and voltage output pins can be tied together.



V_{BOOST_x}

R2

R3

R3

T1

DAC

RSET

Figure 73. Voltage-to-Current Conversion Circuitry

Voltage Output Amplifier

The voltage output amplifier is capable of generating both unipolar and bipolar output voltages. It is capable of driving a load of 1 k Ω in parallel with 1 μ F (with an external compensation capacitor) to AGND. The source and sink capabilities of the output amplifier are shown in Figure 23. The slew rate is 1.9 V/ μ s with a full-scale settling time of 16 μ s (10 V step). If remote sensing of the load is not required, connect +V_{SENSE_x} directly to V_{OUT_x}. + V_{SENSE_x} must stay within ±3.0 V of V_{OUT_x} for correct operation.

Driving Large Capacitive Loads

The voltage output amplifier is capable of driving capacitive loads of up to 2 μF with the addition of a 220 pF nonpolarized compensation capacitor on each channel. Care should be taken to choose an appropriate value of compensation capacitor. This capacitor, while allowing the AD5755-1 to drive higher capacitive loads and reduce overshoot, increases the settling time of the part and, therefore, affects the bandwidth of the system. Without the compensation capacitor, up to 10 nF capacitive loads can be driven. See Table 5 for information on connecting compensation capacitors.

Reference Buffers

The AD5755-1 can operate with either an external or internal reference. The reference input requires a 5 V reference for specified performance. This input voltage is then buffered before it is applied to the DAC.

POWER-ON STATE OF THE AD5755-1

On initial power-up of the AD5755-1, the power-on reset circuit powers up in a state that is dependent on the power-on condition (POC) pin.

If POC = 0, the voltage output and current output channels power up in tristate mode.

If POC = 1, the voltage output channel powers up with a 30 k Ω pull-down resistor to ground, and the current output channel powers up to tristate.

Even though the output ranges are not enabled, the default output range is 0 V to 5 V, and the clear code register is loaded

with all zeros. This means that if the user clears the part after power-up, the output is actively driven to 0 V (if the channel has been enabled for clear).

SERIAL INTERFACE

The AD5755-1 is controlled over a versatile 3-wire serial interface that operates at clock rates of up to 30 MHz and is compatible with SPI, QSPI, MICROWIRE, and DSP standards. Data coding is always straight binary.

Input Shift Register

The input shift register is 24 bits wide. Data is loaded into the device MSB first as a 24-bit word under the control of a serial clock input, SCLK. Data is clocked in on the falling edge of SCLK.

If packet error checking, or PEC (see the Device Features section), is enabled, an additional eight bits must be written to the AD5755-1, creating a 32-bit serial interface.

There are two ways in which the DAC outputs can be updated: individual updating or simultaneous updating of all DACs.

Individual DAC Updating

In this mode, $\overline{\text{LDAC}}$ is held low while data is being clocked into the DAC data register. The addressed DAC output is updated on the rising edge of $\overline{\text{SYNC}}$. See Table 3 and Figure 3 for timing information.

Simultaneous Updating of All DACs

In this mode, $\overline{\text{LDAC}}$ is held high while data is being clocked into the DAC data register. Only the first write to each channel's DAC data register is valid after $\overline{\text{LDAC}}$ is brought high. Any subsequent writes while $\overline{\text{LDAC}}$ is still held high are ignored, though they are loaded into the DAC data register. All the DAC outputs are updated by taking $\overline{\text{LDAC}}$ low after $\overline{\text{SYNC}}$ is taken high.

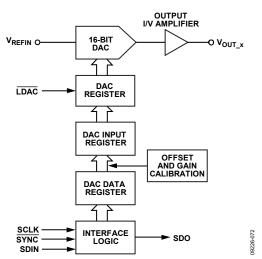


Figure 74. Simplified Serial Interface of Input Loading Circuitry for One DAC Channel

TRANSFER FUNCTION

Table 6 shows the input code to ideal output voltage relationship for the AD5755-1 for straight binary data coding of the $\pm 10 \text{ V}$ output range.

Table 6. Ideal Output Voltage to Input Code Relationship

-	Digit	al Input		
Strai	ight Bina	ry Data (Analog Output	
М	SB	L	SB	V _{OUT}
1111	1111	1111	1111	+2 V _{REF} × (32,767/32,768)
1111	1111	1111	1110	$+2 V_{REF} \times (32,766/32,768)$
1000	0000	0000	0000	0 V
0000	0000	0000	0001	$-2 V_{REF} \times (32,767/32,768)$
0000	0000	0000	0000	−2 V _{REF}

REGISTERS

Table 7 shows an overview of the registers for the AD5755-1.

Table 7. Data, Control, and Readback Registers for the AD5755-1

Register	Description
Data	
DAC Data Register (×4)	Used to write a DAC code to each DAC channel. AD5755-1 data bits = D15 to D0. There are four DAC data registers, one per DAC channel.
Gain Register (×4)	Used to program gain trim, on a per channel basis. AD5755-1 data bits = D15 to D0. There are four gain registers, one per DAC channel.
Offset Register (×4)	Used to program offset trim, on a per channel basis. AD5755-1 data bits = D15 to D0. There are four offset registers, one per DAC channel.
Clear Code Register (×4)	Used to program clear code on a per channel basis. AD5755-1 data bits = D15 to D0. There are four clear code registers, one per DAC channel.
Control	
Main Control Register	Used to configure the part for main operation. Sets functions such as status readback during write, enables output on all channels simultaneously, powers on all dc-to-dc converter blocks simultaneously, and enables and sets conditions of the watchdog timer. See the Device Features section for more details.
Software Register	Has three functions. Used to perform a reset, to toggle the user bit, and, as part of the watchdog timer feature, to verify correct data communication operation.
Slew Rate Control Register (×4)	Used to program the slew rate of the output. There are four slew rate control registers, one per channel.
DAC Control Register (×4)	These registers are used to control the following:
	Set the output range, for example, 4 mA to 20 mA, 0 V to 10 V.
	Set whether an internal/external sense resistor is used.
	Enable/disable a channel for CLEAR.
	Enable/disable overrange.
	Enable/disable internal circuitry on a per channel basis.
	Enable/disable output on a per channel basis.
	Power on dc-to-dc converters on a per channel basis.
	There are four DAC control registers, one per DAC channel.
DC-to-DC Control Register	Use to set the dc-to-dc control parameters. Can control dc-to-dc maximum voltage, phase, and frequency.
Readback	
Status Register	This contains any fault information, as well as a user toggle bit.

PROGRAMMING SEQUENCE TO WRITE/ENABLE THE OUTPUT CORRECTLY

To correctly write to and set up the part from a power-on condition, use the following sequence:

- 1. Perform a hardware or software reset after initial power-on.
- The dc-to-dc converter supply block must be configured. Set the dc-to-dc switching frequency, maximum output voltage allowed, and the phase that the four dc-to-dc channels clock at.
- Configure the DAC control register on a per channel basis.
 The output range is selected, and the dc-to-dc converter block is enabled (DC_DC bit). Other control bits can be configured at this point. Set the INT_ENABLE bit; however, the output enable bit (OUTEN) should not be set.
- 4. Write the required code to the DAC data register. This implements a full DAC calibration internally. Allow at least 200 μs before Step 5 for reduced output glitch.
- 5. Write to the DAC control register again to enable the output (set the OUTEN bit).

A flowchart of this sequence is shown in Figure 75.

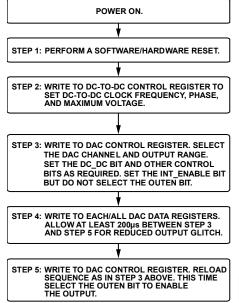


Figure 75. Programming Sequence for Enabling the Output Correctly

CHANGING AND REPROGRAMMING THE RANGE

When changing between ranges, the same sequence as described in the Programming Sequence to Write/Enable the Output Correctly section should be used. It is recommended to set the range to its zero point (can be midscale or zero scale) prior to disabling the output. Because the dc-to-dc switching frequency, maximum voltage, and phase have already been selected, there is no need to reprogram these. A flowchart of this sequence is shown in Figure 76.

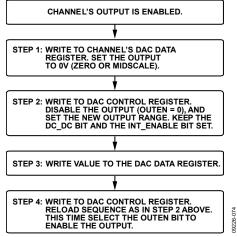


Figure 76. Steps for Changing the Output Range

DATA REGISTERS

The input register is 24 bits wide. When PEC is enabled, the input register is 32 bits wide, with the last eight bits corresponding to the PEC code (see the Packet Error Checking section for more information on PEC). When writing to a data register, the format in Table 8 must be used.

DAC Data Register

When writing to the AD5755-1 DAC data registers, D15 to D0 are used for DAC data bits. Table 10 shows the register format and Table 9 describes the function of Bit D23 to Bit D16.

These are don't cares if they are not relevant to the operation being performed.

Table 8. Writing to a Data Register

MSB								LSB
D23	D22	D21	D20	D19	D18	D17	D16	D15 to D0
R/W	DUT AD1	DUT AD0	DREG2	DREG1	DREG0	DAC AD1	DAC AD0	Data

Bit	Description	Description									
R/W		ad from or a writ	te to the addre	essed register.							
DUT_AD1, DUT_AD0	Used in association with the external pins, AD1 and AD0, to determine which AD5755-1 device is being addressed by the system controller.										
	DUT_AD1	DUT_AD0	Function								
	0	0	Addresses	part with Pin A	D1 = 0, Pin AD0 =	= 0					
	0	1	Addresses	part with Pin A	D1 = 0, Pin AD0 =	= 1					
	1	0	Addresses	part with Pin A	D1 = 1, Pin AD0 =	= 0					
	1	1	Addresses part with Pin AD1 = 1, Pin AD0 = 1								
DREG2, DREG1, DREG0			data register or a control register is written to. If a control register is selected, a further decode able 17) is required to select the particular control register, as follows.								
	DREG2 DREG1 DREG0 Function										
	0	0	0 Write to DAC data register (individual channel write)								
	0	1	0 Write to gain register								
	0	1	1	Write to gai	n register (all DAC	Cs)					
	1	0	0	Write to offs	et register						
	1	0	1	Write to offs	et register (all DA	ACs)					
	1	1	0	Write to clea	r code register						
	1	1	1	Write to a co	ontrol register						
DAC_AD1, DAC_AD0	These bits are	e used to decode	the DAC char	nnel.							
	DAC_AD1	DAC_AD0	DAC Channel/Register Address								
	0	0	DAC A								
			1								
	0	1	DAC B								
	0	1 0	DAC B DAC C								

Table 10. Programming the DAC Data Registers

Χ

Χ

MSB								LSB
D23	D22	D21	D20	D19	D18	D17	D16	D15 to D0
R/W	DUT_AD1	DUT_AD0	DREG2	DREG1	DREG0	DAC_AD1	DAC_AD0	DAC data

Gain Register

The 16-bit gain register, as shown in Table 11, allows the user to adjust the gain of each channel in steps of 1 LSB. This is done by setting the DREG[2:0] bits to 010. It is possible to write the same gain code to all four DAC channels at the same time by setting the DREG[2:0] bits to 011. The gain register coding is straight binary as shown in Table 12. The default code in the gain register is 0xFFFF. In theory, the gain can be tuned across the full range of the output. In practice, the maximum recommended gain trim is about 50% of programmed range to maintain accuracy. See the Digital Offset and Gain Control section for more information.

Offset Register

The 16-bit offset register, as shown in Table 13, allows the user to adjust the offset of each channel by -32,768 LSBs to +32,767 LSBs

in steps of 1 LSB. This is done by setting the DREG[2:0] bits to 100. It is possible to write the same offset code to all four DAC channels at the same time by setting the DREG[2:0] bits to 101. The offset register coding is straight binary as shown in Table 14. The default code in the offset register is 0x8000, which results in zero offset programmed to the output. See the Digital Offset and Gain Control section for more information.

Clear Code Register

The 16-bit clear code register allows the user to set the clear value of each channel as shown in Table 15. It is possible, via software, to enable or disable on a per channel basis which channels are cleared when the CLEAR pin is activated. The default clear code is 0x0000. See the Asynchronous Clear section for more information.

Table 11. Programming the Gain Register

R/W	DUT_AD1	DUT_AD0	DREG2	DREG1	DREG0	DAC_AD1	DAC_AD0	D15 to D0
0	Device a	Device address		1	0	DAC channel address		Gain adjustment

Table 12. Gain Register

Gain Adjustment	G15	G14	G13	G12 to G4	G3	G2	G1	G0
+65,535 LSBs	1	1	1	1	1	1	1	1
+65,534 LSBs	1	1	1	1	1	1	0	0
•••								
1 LSB	0	0	0	0	0	0	0	1
0 LSBs	0	0	0	0	0	0	0	0

Table 13. Programming the Offset Register

R/W	DUT_AD1	DUT_AD0	DREG2	DREG1	DREG0	DAC_AD1	DAC_AD0	D15 to D0
0	Devic	e address	1	0	0	DAC chan	nel address	Offset adjustment

Table 14. Offset Register Options

Offset Adjustment	OF15	OF14	OF13	OF12 to OF4	OF3	OF2	OF1	OF0
+32,767 LSBs	1	1	1	1	1	1	1	1
+32,766 LSBs	1	1	1	1	1	1	0	0
No Adjustment (Default)	1	0	0	0	0	0	0	0
•••								
–32,767 LSBs	0	0	0	0	0	0	0	0
−32,768 LSBs	0	0	0	0	0	0	0	0

Table 15. Programming the Clear Code Register

R/W	DUT_AD1	DUT_AD0	DREG2	DREG1	DREG0	DAC_AD1	DAC_AD0	D15 to D0
0	Device add	dress	1	1	0	DAC char	inel address	Clear code

CONTROL REGISTERS

When writing to a control register, the format shown in Table 16 must be used. See Table 9 for information on the configuration of Bit D23 to Bit D16. The control registers are addressed by setting the DREG[2:0] bits to 111 and then setting the CREG[2:0] bits to the appropriate decode address for that register, according to Table 17. These CREG bits select among the various control registers.

Main Control Register

The main control register options are shown in Table 18 and Table 19. See the Device Features section for more information on the features controlled by the main control register.

Table 16. Writing to a Control Register

MSB

LSB

D23	D22	D21	D20	D19	D18	D17	D16	D15	D14	D13	D12 to D0
R/W	DUT_AD1	DUT_AD0	1	1	1	DAC_AD1	DAC_AD0	CREG2	CREG1	CREG0	Data

Table 17. Register Access Decode

CREG2 (D15)	CREG1 (D14)	CREG0 (D13)	Function
0	0	0	Slew rate control register (one per channel)
0	0	1	Main control register
0	1	0	DAC control register (one per channel)
0	1	1	DC-to-dc control register
1	0	0	Software register (one per channel)

Table 18. Programming the Main Control Register

MSB

LSB

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3 to D0
0	0	1	POC	STATREAD	EWD	WD1	WD0	X ¹	ShtCctLim	OUTEN_ALL	DCDC_ALL	X ¹

 $^{^{1}}$ X = don't care.

Table 19. Main Control Register Functions

Bit	Description						
POC	The POC bit of	determines the	state of the voltage output channels during normal operation. Its default value is 0.				
	POC = 0. The	output goes to	the value set by the POC hardware pin when the voltage output is not enabled (default).				
	POC = 1. The	output goes to	o the opposite value of the POC hardware pin if the voltage output is not enabled.				
STATREAD	Enable status readback during a write. See the Device Features section.						
	STATREAD =	1, enable.					
	STATREAD =	0, disable (defa	ault).				
EWD	Enable watch	ndog timer. See	e the Device Features section for more information.				
	EWD = 1, ena	able watchdog					
	EWD = 0, disa	able watchdog	(default).				
WD1, WD0	Timeout sele	ct bits. Used to	select the timeout period for the watchdog timer.				
	WD1	WD0	Timeout Period (ms)				
	0	0	5				
	0	1	10				
	1	0	100				
	1	1	200				
ShtCctLim	Programmab	le short-circuit	: limit on the Vout_x pin in the event of a short-circuit condition.				
	0 = 16 mA (d)	efault).					
	1 = 8 mA.						
OUTEN_ALL	Enables the o	output on all fo	our DACs simultaneously.				
	Do not use the OUTEN_ALL bit when using the OUTEN bit in the DAC control register.						
DCDC_ALL	When set, po	wers up the do	t-to-dc converter on all four channels simultaneously.				
	To power do	wn the dc-to-d	c converters, all channel outputs must first be disabled.				
	Do not use th	ne DCDC_ALL I	oit when using the DC_DC bit in the DAC control register.				

DAC Control Register

The DAC control register is used to configure each DAC channel. The DAC control register options are shown in Table 20 and Table 21.

Table 20. Programming DAC Control Register

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	1	0	X ¹	X ¹	X ¹	X ¹	INT_ENABLE	CLR_EN	OUTEN	RSET	DC_DC	OVRNG	R2	R1	R0

 $^{^{1}}$ X = don't care.

Table 21. DAC Control Register Functions

Bit	Description								
INT_ENABLE	Powers up the dc-to-dc converter, DAC, and internal amplifiers for the selected channel. Does not enable the output. Can only be done on a per channel basis. It is recommended to set this bit and allow a >200 µs delay before enabling the output because this results in a reduced output enable glitch. See Figure 30 and Figure 48 for plots of this glitch.								
CLR_EN	Per channel clear enable bit. Selects if this channel clears when the CLEAR pin is activated.								
			hen the part is						
OUTEN				ne part is cleared (default).					
OUTEN		les the selected hables the chan	d output chann	iel.					
	1	sables the char							
RSET	<u> </u>			resistor for the selected DAC channel.					
	RSET = 0, selec	RSET = 0, selects the external resistor (default).							
	RSET = 1, selec	cts the internal	resistor.						
DC_DC	Powers the do	Powers the dc-to-dc converter on the selected channel.							
	DC_DC = 1, power up the dc-to-dc converter.								
		DC_DC = 0, power down the dc-to-dc converter (default).							
	This allows per channel dc-to-dc converter power-up/power-down. To power down the dc-to-dc converter, the OUTEN and INT_ENABLE bits must also be set to 0.								
	All dc-to-dc converters can also be powered up simultaneously using the DCDC_ALL bit in the main control register.								
OVRNG	+			channel only. No current output overrange available.					
	OVRNG = 1, er	_	J ,	, , , , , , , , , , , , , , , , , , , ,					
	OVRNG = 0, disabled (default).								
R2, R1, R0	Selects the ou	tput range to b	e enabled.						
	R2	R1	RO	Output Range Selected					
	0	0	0	0 V to 5 V voltage range (default).					
	0	0 0 1		0 V to 10 V voltage range.					
	0	1	0	±5 V voltage range.					
	0	1	1	±10 V voltage range.					
	1	0	0	4 mA to 20 mA current range.					
	1	0	1	0 mA to 20 mA current range.					
	1	1	0	0 mA to 24 mA current range.					

Software Register

The software register has three functions. It allows the user to perform a software reset to the part. It can be used to set the user toggle bit, D11, in the status register. It is also used as part of the watchdog feature when it is enabled. This feature is useful to ensure that communication has not been lost between the MCU and the AD5755-1 and that the datapath lines are working properly (that is, SDIN, SCLK, and $\overline{\text{SYNC}}$).

When the watchdog feature is enabled, the user must write 0x195 to the software register within the timeout period. If this command is not received within the timeout period, the ALERT pin signals a fault condition. This is only required when the watchdog timer function is enabled.

DC-to-DC Control Register

The dc-to-dc control register allows the user control over the dc-to-dc switching frequency and phase, as well as the maximum allowable dc-to-dc output voltage. The dc-to-dc control register options are shown in Table 24 and Table 25.

Table 22. Programming the Software Register

MSB	LSB			
D15	D14	D13	D12	D11 to D0
1	0	0	User program	Reset code/SPI code

Table 23	Software	Register	Functions
i abie 25.	Sontware	Register	runctions

Bit	Description					
User Program	This bit is mapped to Bit D11 of the status register. When this bit is set to 1, Bit D11 of the status register is set to 1. Likewise, when D12 is set to 0, Bit D11 of the status register is also set to zero. This feature can be used to ensure that the SPI pins are working correctly by writing a known bit value to this register and reading back the corresponding bit from the status register.					
Reset Code/SPI Code	Option	Description				
	Reset code	Writing 0x555 to D[11:0] performs a reset of the AD5755-1.				
	SPI code	If the watchdog timer feature is enabled, 0x195 must be written to the software register (D11 to D0) within the programmed timeout period.				

Table 24. Programming the DC-to-DC Control Register

INIDE							LSB
D15	D14	D13	D12 to D7	D6	D5 to D4	D3 to D2	D1 to D0
0	1	1	X ¹	DC-DC Comp	DC-DC phase	DC-DC Freq	DC-DC MaxV

¹ X = don't care.

Table 25. DC-to-DC Control Register Options

Bit	Description
DC-DC Comp	Selects between an internal and external compensation resistor for the dc-to-dc converter. See the DC-to-DC Converter Compensation Capacitors and Alcc Supply Requirements—Slewing sections in the Device Features section for more information.
	$0 =$ selects the internal 150 k Ω compensation resistor (default).
	1 = bypasses the internal compensation resistor for the dc-to-dc converter. In this mode, an external dc-to-dc compensation resistor must be used; this is placed at the COMP _{DCDC_x} pin in series with the 10 nF dc-to-dc compensation capacitor to ground. Typically, a \sim 50 k Ω resistor is recommended.
DC-DC Phase	User programmable dc-to-dc converter phase (between channels).
	00 = all dc-to-dc converters clock on the same edge (default).
	01 = Channel A and Channel B clock on the same edge, Channel C and Channel D clock on opposite edges.
	10 = Channel A and Channel C clock on the same edge, Channel B and Channel D clock on opposite edges.
	11 = Channel A, Channel B, Channel C, and Channel D clock 90° out of phase from each other.
DC-DC Freq	DC-to-dc switching frequency; these are divided down from the internal 13 MHz oscillator (see Figure 69 and Figure 70).
	$00 = 250 \pm 10\%$ kHz.
	$01 = 410 \pm 10\%$ kHz (default).
	$10 = 650 \pm 10\%$ kHz.
DC-DC MaxV	Maximum allowed V _{BOOST_x} voltage supplied by the dc-to-dc converter.
	00 = 23 V + 1 V/-1.5 V (default).
	$01 = 24.5 \text{ V} \pm 1 \text{ V}.$
	$10 = 27 \text{ V} \pm 1 \text{ V}.$
	$11 = 29.5 \text{ V} \pm 1\text{ V}.$

Slew Rate Control Register

This register is used to program the slew rate control for the selected DAC channel. This feature is available on both the current and voltage outputs. The slew rate control is enabled/disabled and programmed on a per channel basis. See Table 26 and the Digital Slew Rate Control section for more information.

READBACK OPERATION

Readback mode is invoked by setting the R/\overline{W} bit = 1 in the serial input register write. See Table 27 for the bits associated with a readback operation. The DUT_AD1 and DUT_AD0 bits, in association with Bits RD[4:0], select the register to be read. The remaining data bits in the write sequence are don't cares. During the next SPI transfer (see Figure 4), the data appearing on the SDO output contains the data from the previously

addressed register. This second SPI transfer should either be a request to read yet another register on a third data transfer or 0x1CE000, which is the no operation command.

Readback Example

To read back the gain register of Device 1, Channel A on the AD5755-1, implement the following sequence:

- Write 0xA80000 to the AD5755-1 input register. This
 configures the AD5755-1 Device Address 1 for read mode
 with the gain register of Channel A selected. All the data
 bits, D15 to D0, are don't cares.
- 2. Follow with another read command or a no operation command (0x1CE000). During this command, the data from the Channel A gain register is clocked out on the SDO line.

Table 26. Programming the Slew Rate Control Register

D15	D14	D13	D12	D11 to D7	D6 to D3	D2 to D0
0	0	0	SE	X ¹	SR_CLOCK	SR_STEP

¹ X = don't care.

Table 27. Input Shift Register Contents for a Read Operation

D23	D22	D21	D20	D19	D18	D17	D16	D15 to D0
R/W	DUT_AD1	DUT_AD0	RD4	RD3	RD2	RD1	RD0	X ¹

 $^{^{1}}$ X = don't care.

Table 28. Read Address Decoding

RD4	RD3	RD2	RD1	RD0	Function
0	0	0	0	0	Read DAC A data register
0	0	0	0	1	Read DAC B data register
0	0	0	1	0	Read DAC C data register
0	0	0	1	1	Read DAC D data register
0	0	1	0	0	Read DAC A control register
0	0	1	0	1	Read DAC B control register
0	0	1	1	0	Read DAC C control register
0	0	1	1	1	Read DAC D control register
0	1	0	0	0	Read DAC A gain register
0	1	0	0	1	Read DAC B gain register
0	1	0	1	0	Read DAC C gain register
0	1	0	1	1	Read DAC D gain register
0	1	1	0	0	Read DACA offset register
0	1	1	0	1	Read DAC B offset register
0	1	1	1	0	Read DAC C offset register
0	1	1	1	1	Read DAC D offset register
1	0	0	0	0	Clear DAC A code register
1	0	0	0	1	Clear DAC B code register
1	0	0	1	0	Clear DAC C code register
1	0	0	1	1	Clear DAC D code register
1	0	1	0	0	DAC A slew rate control register
1	0	1	0	1	DAC B slew rate control register
1	0	1	1	0	DAC C slew rate control register
1	0	1	1	1	DAC D slew rate control register
1	1	0	0	0	Read status register
1	1	0	0	1	Read main control register
1	1	0	1	0	Read dc-to-dc control register

Status Register

The status register is a read only register. This register contains any fault information as a well as a ramp active bit and a user toggle bit. When the STATREAD bit in the main control register is set, the status register contents can be read back on

the SDO pin during every write sequence. Alternatively, if the STATREAD bit is not set, the status register can be read using the normal readback operation.

Table 29. Decoding the Status Register

LSB D15 D14 D13 D12 D11 D10 D9 D8 D7 D6 D5 D4 D3 D2 D1 D0 PEC Over DC-DC-DC-DC- $V_{\text{OUT_D}}$ I_{OUT_A} Ramp $V_{\text{OUT C}}$ $V_{\text{OUT_B}}$ $V_{\text{OUT_A}}$ $I_{\text{OUT_D}}$ lout c I_{OUT B} DCD DCC DCB DCA toggle active TEMP fault fault fault fault fault fault fault fault error

Table 30.	Status	Register	Options

Bit	Description
DC-DCD	In current output mode, this bit is set on Channel D if the dc-to-dc converter cannot maintain compliance (it may be reaching its V _{MAX} voltage). In this case, the I _{OUT_D} fault bit is also set. See the DC-to-DC Converter V _{MAX} Functionality section for more information on this bit's operation under this condition.
	In voltage output mode, this bit is set if, on Channel D, the dc-to-dc converter is unable to regulate to 15 V as expected. When this bit is set, it does not result in the FAULT pin going high.
DC-DCC	In current output mode, this bit is set on Channel C if the dc-to-dc converter cannot maintain compliance (it may be reaching its V_{MAX} voltage). In this case, the I_{OUT_C} fault bit is also set. See the DC-to-DC Converter V_{MAX} Functionality section for more information on this bit's operation under this condition.
	In voltage output mode, this bit is set if, on Channel C, the dc-to-dc converter is unable to regulate to 15 V as expected. When this bit is set, it does not result in the FAULT pin going high.
DC-DCB	In current output mode, this bit is set on Channel B if the dc-to-dc converter cannot maintain compliance (it may be reaching its V _{MAX} voltage). In this case, the I _{OUT_B} fault bit is also set. See the DC-to-DC Converter V _{MAX} Functionality section for more information on this bit's operation under this condition.
	In voltage output mode, this bit is set if, on Channel B, the dc-to-dc converter is unable to regulate to 15 V as expected. When this bit is set, it does not result in the FAULT pin going high.
DC-DCA	In current output mode, this bit is set on Channel A if the dc-to-dc converter cannot maintain compliance (it may be reaching its V_{MAX} voltage). In this case, the I_{OUT_A} fault bit is also set. See the DC-to-DC Converter V_{MAX} Functionality section for more information on this bit's operation under this condition.
	In voltage output mode, this bit is set if, on Channel A, the dc-to-dc converter is unable to regulate to 15 V as expected.
	When this bit is set, it does not result in the FAULT pin going high.
User Toggle	User toggle bit. This bit is set or cleared via the software register. This can be used to verify data communications if needed.
PEC Error	Denotes a PEC error on the last data-word received over the SPI interface.
Ramp Active	This bit is set while any one of the output channels is slewing (slew rate control is enabled on at least one channel).
Over TEMP	This bit is set if the AD5755-1 core temperature exceeds approximately 150°C.
V _{OUT_D} Fault	This bit is set if a fault is detected on the V _{OUT_D} pin.
V _{OUT_C} Fault	This bit is set if a fault is detected on the V _{OUT_C} pin.
V _{OUT_В} Fault	This bit is set if a fault is detected on the V _{OUT_B} pin.
V _{OUT_A} Fault	This bit is set if a fault is detected on the V _{OUT_A} pin.
I _{OUT_D} Fault	This bit is set if a fault is detected on the IOUT_D pin.
louт_c Fault	This bit is set if a fault is detected on the lout_c pin.
Io∪т_в Fault	This bit is set if a fault is detected on the IOUT_B pin.
I _{OUT_A} Fault	This bit is set if a fault is detected on the lout_A pin.

DEVICE FEATURES

OUTPUT FAULT

The AD5755-1 is equipped with a FAULT pin, an active low open-drain output allowing several AD5755-1 devices to be connected together to one pull-up resistor for global fault detection. The $\overline{\text{FAULT}}$ pin is forced active by any one of the following fault scenarios:

- The voltage at I_{OUT_x} attempts to rise above the compliance range due to an open-loop circuit or insufficient power supply voltage. The internal circuitry that develops the fault output avoids using a comparator with windowed limits because this requires an actual output error before the FAULT output becomes active. Instead, the signal is generated when the internal amplifier in the output stage has less than approximately 1 V of remaining drive capability. Thus, the FAULT output activates slightly before the compliance limit is reached.
- A short is detected on a voltage output pin. The short-circuit current is limited to 16 mA or 8 mA, which is programmable by the user. If using the AD5755-1 in unipolar supply mode, a short-circuit fault may be generated if the output voltage is below 50 mV.
- An interface error is detected due to a PEC failure. See the Packet Error Checking section.
- If the core temperature of the AD5755-1 exceeds approximately 150°C.

The $V_{\text{OUT_x}}$ fault, $I_{\text{OUT_x}}$ fault, PEC error, and over TEMP bits of the status register are used in conjunction with the FAULT output to inform the user which one of the fault conditions caused the FAULT output to be activated.

VOLTAGE OUTPUT SHORT-CIRCUIT PROTECTION

Under normal operation, the voltage output sinks/sources up to 12 mA and maintains specified operation. The maximum output current or short-circuit current is programmable by the user and can be set to 16 mA or 8 mA. If a short circuit is detected, the FAULT goes low and the relevant short CCT bit in the status register is set.

DIGITAL OFFSET AND GAIN CONTROL

Each DAC channel has a gain (M) and offset (C) register, which allow trimming out of the gain and offset errors of the entire signal chain. Data from the DAC data register is operated on by a digital multiplier and adder controlled by the contents of the M and C registers. The calibrated DAC data is then stored in the DAC input register.

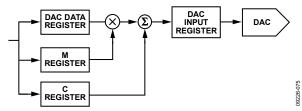


Figure 77. Digital Offset and Gain control

Although Figure 77 indicates a multiplier and adder for each channel, there is only one multiplier and one adder in the device, and they are shared among all four channels. This has implications for the update speed when several channels are updated at once (see Table 3).

Each time data is written to the M or C register, the output is not automatically updated. Instead, the next write to the DAC channel uses these M and C values to perform a new calibration and automatically updates the channel.

The output data from the calibration is routed to the DAC input register. This is then loaded to the DAC as described in the Theory of Operation section. Both the gain register and the offset register have 16 bits of resolution. The correct method to calibrate the gain/offset is to first calibrate out the gain and then calibrate the offset.

The value (in decimal) that is written to the DAC input register can be calculated by

$$Code_{DACRegister} = D \times \frac{(M+1)}{2^{16}} + C - 2^{15}$$
 (1)

where:

D is the code loaded to the DAC channel's input register. *M* is the code in the gain register (default code = $2^{16} - 1$). *C* is the code in the offset register (default code = 2^{15}).

STATUS READBACK DURING A WRITE

The AD5755-1 has the ability to read back the status register contents during every write sequence. This feature is enabled via the STATREAD bit in the main control register. This allows the user to continuously monitor the status register and act quickly in the case of a fault.

When status readback during a write is enabled, the contents of the 16-bit status register (see Table 30) are output on the SDO pin, as shown in Figure 5.

The AD5755-1 powers up with this feature disabled. When this is enabled, the normal readback feature is not available, except for the status register. To read back any other register, clear the STATREAD bit first before following the readback sequence. STATREAD can be set high again after the register read.

ASYNCHRONOUS CLEAR

CLEAR is an active high, edge-sensitive input that allows the output to be cleared to a preprogrammed 16-bit code. This code is user programmable via a per channel 16-bit clear code register.

For a channel to clear, that channel must be enabled to be cleared via the CLR_EN bit in the channel's DAC control register. If the channel is not enabled to be cleared, then the output remains in its current state independent of the CLEAR pin level.

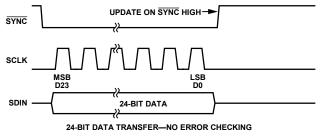
When the CLEAR signal is returned low, the relevant outputs remain cleared until a new value is programmed.

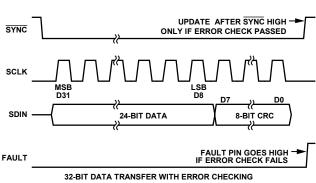
PACKET ERROR CHECKING

To verify that data has been received correctly in noisy environments, the AD5755-1 offers the option of packet error checking based on an 8-bit cyclic redundancy check (CRC-8). The device controlling the AD5755-1 should generate an 8-bit frame check sequence using the polynomial

$$C(x) = x_8 + x_2 + x_1 + 1$$

This is added to the end of the data-word, and 32 bits are sent to the AD5755-1 before taking \$\overline{SYNC}\$ high. If the \$\overline{AD5755-1}\$ sees a 32-bit frame, it performs the error check when \$\overline{SYNC}\$ goes high. If the check is valid, the data is written to the selected register. If the error check fails, the \$\overline{FAULT}\$ pin goes low and the PEC error bit in the status register is set. After reading the status register, \$\overline{FAULT}\$ returns high (assuming there are no other faults), and the PEC error bit is cleared automatically.





The PEC can be used for both transmit and receive of data packets. If status readback during a write is enabled, the PEC values returned during the status readback during a write operation should be ignored. If status readback during a write is

Figure 78. PEC Timing

disabled, the user can still use the normal readback operation to monitor status register activity with PEC.

WATCHDOG TIMER

When enabled, an on-chip watchdog timer generates an alert signal if 0x195 has not been written to the software register within the programmed timeout period. This feature is useful to ensure that communication has not been lost between the MCU and the AD5755-1 and that these datapath lines are working properly (that is, SDIN, SCLK, and SYNC). If 0x195 is not received by the software register within the timeout period, the ALERT pin signals a fault condition. The ALERT signal is active high and can be connected directly to the CLEAR pin to enable a clear in the event that communication from the MCU is lost.

The watchdog timer is enabled, and the timeout period (5 ms, 10 ms, 100 ms, or 200 ms) is set in the main control register (see Table 18 and Table 19).

OUTPUT ALERT

The AD5755-1 is equipped with an ALERT pin. This is an active high CMOS output. The AD5755-1 also has an internal watchdog timer. When enabled, it monitors SPI communications. If 0x195 is not received by the software register within the timeout period, the ALERT pin goes active.

INTERNAL REFERENCE

The AD5755-1 contains an integrated ± 5 V voltage reference with initial accuracy of ± 5 mV maximum and a temperature drift coefficient of ± 10 ppm maximum. The reference voltage is buffered and externally available for use elsewhere within the system.

EXTERNAL CURRENT SETTING RESISTOR

Referring to Figure 73, R_{SET} is an internal sense resistor as part of the voltage-to-current conversion circuitry. The stability of the output current value over temperature is dependent on the stability of the value of R_{SET} . As a method of improving the stability of the output current over temperature, an external $15~\mathrm{k}\Omega$ low drift resistor can be connected to the R_{SET_x} pin of the AD5755-1 to be used instead of the internal resistor, R1. The external resistor is selected via the DAC control register (see Table 20).

Table 1 outlines the performance specifications of the AD5755-1 with both the internal R_{SET} resistor and an external, 15 k Ω R_{SET} resistor. Using an external R_{SET} resistor allows for improved performance over the internal R_{SET} resistor option. The external R_{SET} resistor specification assumes an ideal resistor; the actual performance depends on the absolute value and temperature coefficient of the resistor used. This directly affects the gain error of the output, and thus the total unadjusted error. To arrive at the gain/TUE error of the output with a particular external R_{SET} resistor, add the percentage absolute error of the R_{SET} resistor directly to the gain/TUE error of the AD5755-1 with the external R_{SET} resistor, shown in Table 1 (expressed in % FSR).

HART

The AD5755-1 has four CHART pins, one corresponding to each output channels. A HART signal can be coupled into these pins. The HART signal appears on the corresponding current output, if the output is enabled. Table 31 shows the recommended input voltages for the HART signal at the CHART pin. If these voltages are used, the current output should meet the HART amplitude specifications. Figure 79 shows the recommended circuit for attenuating and coupling in the HART signal.

Table 31. CHART Input Voltage to HART Output Current

R _{SET}	CHART Input Voltage	Current Output (HART)	
Internal R _{SET}	150 mV p-p	1 mA p-p	
External R _{SET}	170 mV p-p	1 mA p-p	

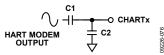


Figure 79. Coupling HART Signal

A minimum capacitance of C1 + C2 is required to ensure that the 1.2 kHz and 2.2 kHz HART frequencies are not significantly attenuated at the output. The recommended values are C1 = 22 nF, C2 = 47 nF.

Digitally controlling the slew rate of the output is necessary to meet the analog rate of change requirements for HART.

DIGITAL SLEW RATE CONTROL

The slew rate control feature of the AD5755-1 allows the user to control the rate at which the output value changes. This feature is available on both the current and voltage outputs. With the slew rate control feature disabled, the output value changes at a rate limited by the output drive circuitry and the attached load. To reduce the slew rate, this can be achieved by enabling the slew rate control feature. With the feature enabled via the SREN bit of the slew rate control register (see Table 26), the output, instead of slewing directly between two values, steps digitally at a rate defined by two parameters accessible via the slew rate control register, as shown in Table 26.

The parameters are SR_CLOCK and SR_STEP. SR_CLOCK defines the rate at which the digital slew is updated, for example, if the selected update rate is 8 kHz, the output updates every 125 μ s. In conjunction with this, SR_STEP defines by how much the output value changes at each update. Together, both parameters define the rate of change of the output value. Table 32 and Table 33 outline the range of values for both the SR_CLOCK and SR_STEP parameters.

Table 32. Slew Rate Update Clock Options

	1 1					
	SR_CLOCK	Update Clock Frequency (Hz) ¹				
	0000	64 k				
	0001	32 k				
	0010	16 k				
	0011	8 k				
	0100	4 k				
	0101	2 k				
	0110	1 k				
	0111	500				
	1000	250				
	1001	125				
	1010	64				
	1011	32				
	1100	16				
	1101	8				
	1110	4				
_	1111	0.5				

¹ These clock frequencies are divided down from the 13 MHz internal oscillator. See Table 1, Figure 69, and Figure 70.

Table 33. Slew Rate Step Size Options

Tuble 33. Siew Rute Step Size Options					
SR_STEP	Step Size (LSBs)				
000	1				
001	2				
010	4				
011	16				
100	32				
101	64				
110	128				
111	256				

The following equation describes the slew rate as a function of the step size, the update clock frequency, and the LSB size:

Slew Time =

Output Change Step Size × Update Clock Frequency × LSB Size

where

Slew Time is expressed in seconds.

Output Change is expressed in amps for I_{OUT_x} or volts for V_{OUT_x}.

When the slew rate control feature is enabled, all output changes occur at the programmed slew rate (see the DC-to-DC Converter Settling Time section for additional information). For example, if the CLEAR pin is asserted, the output slews to the clear value at the programmed slew rate (assuming that the clear channel is enabled to be cleared). If a number of channels are enabled for slew, care must be taken when asserting the CLEAR pin. If one of the channels is slewing when CLEAR is asserted, other channels may change directly to their clear values not under slew rate control. The update clock frequency for any given value is the same for all output ranges. The step size, however, varies across output ranges for a given value of step size because the LSB size is different for each output range.

POWER DISSIPATION CONTROL

The AD5755-1 contains integrated dynamic power control using a dc-to-dc boost converter circuit, allowing reductions in power consumption from standard designs when using the part in current output mode.

In standard current input module designs, the load resistor values can range from typically 50 Ω to 750 Ω . Output module systems must source enough voltage to meet the compliance voltage requirement across the full range of load resistor values. For example, in a 4 mA to 20 mA loop when driving 20 mA, a compliance voltage of >15 V is required. When driving 20 mA into a 50 Ω load, only 1 V compliance is required.

The AD5755-1 circuitry senses the output voltage and regulates this voltage to meet compliance requirements plus a small headroom voltage. The AD5755-1 is capable of driving up to 24 mA through a 1 k Ω load.

DC-TO-DC CONVERTERS

The AD5755-1 contains four independent dc-to-dc converters. These are used to provide dynamic control of the V_{BOOST} supply voltage for each channel (see Figure 73). Figure 80 shows the discreet components needed for the dc-to-dc circuitry, and the following sections describe component selection and operation of this circuitry.

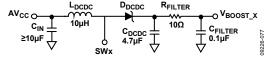


Figure 80. DC-to-DC Circuit

Table 34. Recommended DC-to-DC Components

Symbol	Component	Value	Manufacturer
L _{DCDC}	XAL4040-103	10 μΗ	Coilcraft®
C_{DCDC}	GRM32ER71H475KA88L	4.7 μF	Murata
D_DCDC	PMEG3010BEA	0.38 V _F	NXP

It is recommended to place a 10 Ω , 100 nF low-pass RC filter after C_{DCDC} . This consumes a small amount of power but reduces the amount of ripple on the V_{BOOST_x} supply.

DC-to-DC Converter Operation

The on-board dc-to-dc converters use a constant frequency, peak current mode control scheme to step up an $AV_{\rm CC}$ input of 4.5 V to 5.5 V to drive the AD5755-1 output channel. These are designed to operate in discontinuous conduction mode (DCM) with a duty cycle of <90% typical. Discontinuous conduction mode refers to a mode of operation where the inductor current goes to zero for an appreciable percentage of the switching cycle. The dc-to-dc converters are nonsynchronous; that is, they require an external Schottky diode.

DC-to-DC Converter Output Voltage

When a channel current output is enabled, the converter regulates the V_{BOOST_x} supply to 7.4 V (±5%) or ($I_{OUT} \times R_{LOAD} + Headroom$), whichever is greater (see Figure 53 for a plot of headroom supplied vs. output current). In voltage output mode with the

output disabled, the converter regulates the V_{BOOST_x} supply to +15 V (±5%). In current output mode with the output disabled, the converter regulates the V_{BOOST_x} supply to 7.4 V (±5%).

Within a channel, the V_{OUT_x} and I_{OUT_x} stages share a common V_{BOOST_x} supply so that the outputs of the I_{OUT_x} and V_{OUT_x} stages can be tied together.

DC-to-DC Converter Settling Time

When in current output mode, the settling time for a step greater than ~1 V ($I_{OUT} \times R_{LOAD}$) is dominated by the settling time of the dc-to-dc converter. The exception to this is when the required voltage at the I_{OUT_x} pin plus the compliance voltage is below 7.4 V (±5%). A typical plot of the output settling time can be found in Figure 49. This plot is for a 1 k Ω load. The settling time for smaller loads is faster. The settling time for current steps less than 24 mA is also faster.

DC-to-DC Converter V_{MAX} Functionality

The maximum $V_{\mathrm{BOOST_x}}$ voltage is set in the dc-to-dc control register (23 V, 24.5 V, 27 V, or 29.5 V; see Table 25). On reaching this maximum voltage, the dc-to-dc converter is disabled, and the $V_{\mathrm{BOOST_x}}$ voltage is allowed to decay by ~0.4 V. After the $V_{\mathrm{BOOST_x}}$ voltage has decayed by ~0.4 V, the dc-to-dc converter is reenabled, and the voltage ramps up again to V_{MAX} , if still required. This operation is shown in Figure 81.

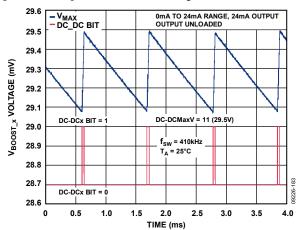


Figure 81. Operation on Reaching V_{MAX}

As can be seen in Figure 81, the DC-DCx bit in the status register asserts when the AD5755-1 is ramping to the V_{MAX} value but deasserts when the voltage is decaying to $V_{MAX} \sim 0.4$ V.

DC-to-DC Converter On-Board Switch

The AD5755-1 contains a 0.425 Ω internal switch. The switch current is monitored on a pulse by pulse basis and is limited to 0.8 A peak current.

DC-to-DC Converter Switching Frequency and Phase

The AD5755-1 dc-to-dc converter switching frequency can be selected from the dc-to-dc control register. The phasing of the channels can also be adjusted so that the dc-to-dc converter can clock on different edges (see Table 25). For typical applications, a 410 kHz frequency is recommended. At light loads (low output

current and small load resistor), the dc-to-dc converter enters a pulse-skipping mode to minimize switching power dissipation.

DC-to-DC Converter Inductor Selection

For typical 4 mA to 20 mA applications, a 10 μH inductor (such as the XAL4040-103 from Coilcraft), combined with a switching frequency of 410 kHz, allows up to 24 mA to be driven into a load resistance of up to 1 k Ω with an AV $_{\rm CC}$ supply of 4.5 V to 5.5 V. It is important to ensure that the inductor is able to handle the peak current without saturating, especially at the maximum ambient temperature. If the inductor enters into saturation mode, it results in a decrease in efficiency. The inductance value also drops during saturation and may result in the dc-to-dc converter circuit not being able to supply the required output power.

DC-to-DC Converter External Schottky Selection

The AD5755-1 requires an external Schottky for correct operation. Ensure that the Schottky is rated to handle the maximum reverse breakdown expected in operation and that the rectifier maximum junction temperature is not exceeded. The diode average current is approximately equal to the $I_{\rm LOAD}$ current. Diodes with larger forward voltage drops result in a decrease in efficiency.

DC-to-DC Converter Compensation Capacitors

As the dc-to-dc converter operates in DCM, the uncompensated transfer function is essentially a single-pole transfer function. The pole frequency of the transfer function is determined by the dc-to-dc converter's output capacitance, input and output voltage, and output load. The AD5755-1 uses an external capacitor in conjunction with an internal $150~\mathrm{k}\Omega$ resistor to compensate the regulator loop. Alternatively, an external compensation resistor can be used in series with the compensation capacitor, by setting the DC-DC Comp bit in the dc-to-dc control register. In this case, a ${\sim}50~\mathrm{k}\Omega$ resistor is recommended. A description of the advantages of this can be found in the AI_CC Supply Requirements—Slewing section. For typical applications, a 10 nF dc-to-dc compensation capacitor is recommended.

DC-to-DC Converter Input and Output Capacitor Selection

The output capacitor affects ripple voltage of the dc-to-dc converter and indirectly limits the maximum slew rate at which the channel output current can rise. The ripple voltage is caused by a combination of the capacitance and equivalent series resistance (ESR) of the capacitor. For the AD5755-1, a ceramic capacitor of 4.7 μF is recommended for typical applications. Larger capacitors or paralleled capacitors improve the ripple at the expense of reduced slew rate. Larger capacitors also impact the AV $_{\rm CC}$ supplies current requirements while slewing (see the AI $_{\rm CC}$ Supply Requirements—Slewing section). This capacitance at the output of the dc-to-dc converter should be >3 μF under all operating conditions.

The input capacitor provides much of the dynamic current required for the dc-to-dc converter and should be a low ESR

component. For the AD5755-1, a low ESR tantalum or ceramic capacitor of $10~\mu F$ is recommended for typical applications. Ceramic capacitors must be chosen carefully because they can exhibit a large sensitivity to dc bias voltages and temperature. X5R or X7R dielectrics are preferred because these capacitors remain stable over wider operating voltage and temperature ranges. Care must be taken if selecting a tantalum capacitor to ensure a low ESR value.

AICC SUPPLY REQUIREMENTS—STATIC

The dc-to-dc converter is designed to supply a $V_{\text{BOOST_x}}$ voltage of

$$V_{BOOST} = I_{OUT} \times R_{LOAD} + Headroom$$
 (2)

See Figure 53 for a plot of headroom supplied vs. output voltage. This means that, for a fixed load and output voltage, the dc-to-dc converter output current can be calculated by the following formula:

$$AI_{CC} = \frac{Power\ Out}{Efficiency \times AV_{CC}} = \frac{I_{OUT} \times V_{BOOST}}{\eta_{V_{BOOST}} \times AV_{CC}}$$
 (3)

where:

 I_{OUT} is the output current from I_{OUT_x} in amps. $\eta_{V_{BOOST_x}}$ is the efficiency at V_{BOOST_x} as a fraction (see Figure 55 and Figure 56).

AIcc SUPPLY REQUIREMENTS—SLEWING

The $AI_{\rm CC}$ current requirement while slewing is greater than in static operation because the output power increases to charge the output capacitance of the dc-to-dc converter. This transient current can be quite large (see Figure 82), although the methods described in the Reducing $AI_{\rm CC}$ Current Requirements section can reduce the requirements on the $AV_{\rm CC}$ supply. If not enough $AI_{\rm CC}$ current can be provided, the $AV_{\rm CC}$ voltage drops. Due to this $AV_{\rm CC}$ drop, the $AI_{\rm CC}$ current required to slew increases further. This means that the voltage at $AV_{\rm CC}$ drops further (see Equation 3) and the $V_{\rm BOOST_x}$ voltage, and thus the output voltage, may never reach its intended value. Because this $AV_{\rm CC}$ voltage is common to all channels, this may also affect other channels.

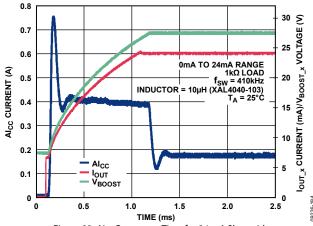


Figure 82. Al_{CC} Current vs. Time for 24 mA Slew with Internal Compensation Resistor

Reducing Alcc Current Requirements

There are two main methods that can be used to reduce the AI_{CC} current requirements. One method is to add an external compensation resistor, and the other is to use slew rate control. Both of these methods can be used in conjunction.

A compensation resistor can be placed at the COMP_{DCDC_x} pin in series with the 10 nF compensation capacitor. A 51 k Ω external compensation resistor is recommended. This compensation increases the slew time of the current output but eases the AI_{CC} transient current requirements. Figure 83 shows a plot of AI_{CC} current for a 24 mA step through a 1 k Ω load when using a 51 k Ω compensation resistor. This method eases the current requirements through smaller loads even further, as shown in Figure 84.

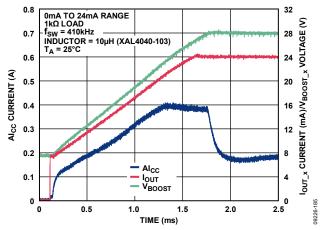


Figure 83. Alcc Current vs. Time for 24 mA Through 1 $k\Omega$ Slew with External 51 $k\Omega$ Compensation Resistor

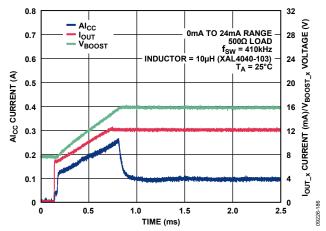


Figure 84. Alcc Current vs. Time for 24 mA Through 500 Ω Slew with External 51 k Ω Compensation Resistor

Using slew rate control can greatly reduce the $AV_{\rm CC}$ supplies current requirements, as shown in Figure 85. When using slew rate control, attention should be paid to the fact that the output cannot slew faster than the dc-to-dc converter. The dc-to-dc converter slews slowest at higher currents through large (for example, $1~\rm k\Omega)$ loads. This slew rate is also dependent on the configuration of the dc-to-dc converter. Two examples of the dc-to-dc converter output slew are shown in Figure 83 and Figure 84 ($V_{\rm BOOST}$ corresponds to the dc-to-dc converter's output voltage).

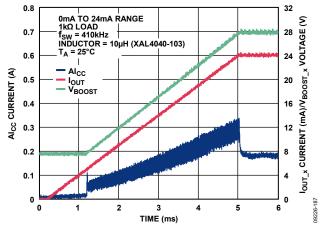


Figure 85. Alcc Current vs. Time for 24 mA Slew with Slew Rate Control

APPLICATIONS INFORMATION

VOLTAGE AND CURRENT OUTPUT RANGES ON THE SAME TERMINAL

When using a channel of the AD5755-1, the current and voltage output pins can be connected to two separate terminals or tied together and connected to a single terminal. There is no conflict with tying the two output pins together because only the voltage output or the current output can be enabled at any one time. When the current output is enabled, the voltage output is in tristate mode, and when the voltage output is enabled, the current output is in tristate mode. For this operation, the POC pin must be tied low and the POC bit in the main control register set to 0, or, if the POC pin is tied high, the POC bit in the main control register must be set to 1 before the current output is enabled.

As shown in the Absolute Maximum Ratings section, the output tolerances are the same for both the voltage and current output pins. The $+V_{SENSE_x}$ connections are buffered so that current leakage into these pins is negligible when in current output mode.

CURRENT OUTPUT MODE WITH INTERNAL RSET

When using the internal R_{SET} resistor in current output mode, the output is significantly affected by how many other channels using the internal R_{SET} are enabled and by the dc crosstalk from these channels. The internal R_{SET} specifications in Table 1 are for all channels enabled with the internal R_{SET} selected and outputting the same code.

For every channel enabled with the internal R_{SET} , the offset error decreases. For example, with one current output enabled using the internal R_{SET} , the offset error is 0.075% FSR. This value decreases proportionally as more current channels are enabled; the offset error is 0.056% FSR on each of two channels, 0.029% on each of three channels, and 0.01% on each of four channels.

Similarly, the dc crosstalk when using the internal R_{SET} is proportional to the number of current output channels enabled with the internal R_{SET} . For example, with the measured channel at 0x8000 and one channel going from zero to full scale, the dc crosstalk is -0.011% FSR. With two channels going from zero to full scale, it is -0.019% FSR, and with all three other channels going from zero to full scale, it is -0.025% FSR.

For the full-scale error measurement in Table 1, all channels are at 0xFFFF. This means that, as any channel goes to zero scale, the full-scale error increases due to the dc crosstalk. For example, with the measured channel at 0xFFFF and three

channels at zero scale, the full-scale error is 0.025%. Similarly, if only one channel is enabled in current output mode with the internal R_{SET} , the full-scale error is 0.025% FSR + 0.075% FSR = 0.1% FSR.

PRECISION VOLTAGE REFERENCE SELECTION

To achieve the optimum performance from the AD5755-1 over its full operating temperature range, a precision voltage reference must be used. Thought should be given to the selection of a precision voltage reference. The voltage applied to the reference inputs is used to provide a buffered reference for the DAC cores. Therefore, any error in the voltage reference is reflected in the outputs of the device.

There are four possible sources of error to consider when choosing a voltage reference for high accuracy applications: initial accuracy, temperature coefficient of the output voltage, long term drift, and output voltage noise.

Initial accuracy error on the output voltage of an external reference can lead to a full-scale error in the DAC. Therefore, to minimize these errors, a reference with low initial accuracy error specification is preferred. Choosing a reference with an output trim adjustment, such as the ADR425, allows a system designer to trim system errors out by setting the reference voltage to a voltage other than the nominal. The trim adjustment can be used at any temperature to trim out any error.

Long-term drift is a measure of how much the reference output voltage drifts over time. A reference with a tight long-term drift specification ensures that the overall solution remains relatively stable over its entire lifetime.

The temperature coefficient of a reference's output voltage affects INL, DNL, and TUE. A reference with a tight temperature coefficient specification should be chosen to reduce the dependence of the DAC output voltage to ambient temperature.

In high accuracy applications, which have a relatively low noise budget, reference output voltage noise must be considered. Choosing a reference with as low an output noise voltage as practical for the system resolution required is important. Precision voltage references such as the ADR435 (XFET design) produce low output noise in the 0.1 Hz to 10 Hz region. However, as the circuit bandwidth increases, filtering the output of the reference may be required to minimize the output noise.

Table 35. Recommended Precision References

Part No.	Initial Accuracy (mV Maximum)	Long-Term Drift (ppm Typical)	Temperature Drift (ppm/°C Maximum)	0.1 Hz to 10 Hz Noise (μV p-p Typical)
ADR445	±2	50	3	2.25
ADR02	±3	50	3	10
ADR435	±2	40	3	8
ADR395	±5	50	9	8
AD586	±2.5	15	10	4

DRIVING INDUCTIVE LOADS

When driving inductive or poorly defined loads, a capacitor may be required between I_{OUT_x} and AGND to ensure stability. A 0.01 μ F capacitor between I_{OUT_x} and AGND ensures stability of a load of 50 mH. The capacitive component of the load may cause slower settling, although this may be masked by the settling time of the AD5755-1. There is no maximum capacitance limit for the current output of the AD5755-1.

TRANSIENT VOLTAGE PROTECTION

The AD5755-1 contains ESD protection diodes that prevent damage from normal handling. The industrial control environment can, however, subject I/O circuits to much higher transients. To protect the AD5755-1 from excessively high voltage transients, external power diodes and a surge current limiting resistor are required, as shown in Figure 86. The two protection diodes and resistor must have appropriate power ratings. Further protection can be provided with transient voltage suppressors or transorbs; these are available as both unidirectional suppressors (protect against positive high voltage transients) and bidirectional suppressors (protect against both positive and negative high voltage transients) and are available in a wide range of standoff and breakdown voltage ratings. It is recommended that all field connected nodes be protected.

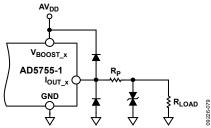


Figure 86. Output Transient Voltage Protection

MICROPROCESSOR INTERFACING

Microprocessor interfacing to the AD5755-1 is via a serial bus that uses a protocol compatible with microcontrollers and DSP processors. The communications channel is a 3-wire minimum interface consisting of a clock signal, a data signal, and a latch signal. The AD5755-1 requires a 24-bit data-word with data valid on the falling edge of SCLK.

 $\overline{\text{LDAC}}$ output update is initiated on either the rising edge of $\overline{\text{LDAC}}$ or, if $\overline{\text{LDAC}}$ is held low, on the rising edge of $\overline{\text{SYNC}}$. The contents of the registers can be read using the readback function.

AD5755-1-TO-ADSP-BF527 INTERFACE

The AD5755-1 can be connected directly to the SPORT interface of the ADSP-BF527, an Analog Devices, Inc., Blackfin* DSP. Figure 87 shows how the SPORT interface can be connected to control the AD5755-1.

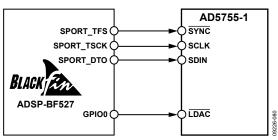


Figure 87. AD5755-1-to-ADSP-BF527 SPORT Interface

LAYOUT GUIDELINES

Grounding

In any circuit where accuracy is important, careful consideration of the power supply and ground return layout helps to ensure the rated performance. The printed circuit board on which the AD5755-1 is mounted should be designed so that the analog and digital sections are separated and confined to certain areas of the board. If the AD5755-1 is in a system where multiple devices require an AGND-to-DGND connection, the connection should be made at one point only. The star ground point should be established as close as possible to the device.

The GNDSW $_x$ and ground connection for the AV $_{\rm CC}$ supply are referred to as PGND. PGND should be confined to certain areas of the board, and the PGND-to-AGND connection should be made at one point only.

Supply Decoupling

The AD5755-1 should have ample supply bypassing of 10 μF in parallel with 0.1 μF on each supply located as close to the package as possible, ideally right up against the device. The 10 μF capacitors are the tantalum bead type. The 0.1 μF capacitor should have low effective series resistance (ESR) and low effective series inductance (ESL), such as the common ceramic types, which provide a low impedance path to ground at high frequencies to handle transient currents due to internal logic switching.

Traces

The power supply lines of the AD5755-1 should use as large a trace as possible to provide low impedance paths and reduce the effects of glitches on the power supply line. Fast switching signals such as clocks should be shielded with digital ground to prevent radiating noise to other parts of the board and should never be run near the reference inputs. A ground line routed between the SDIN and SCLK lines helps reduce crosstalk between them (not required on a multilayer board that has a separate ground plane, but separating the lines helps). It is essential to minimize noise on the REFIN line because it couples through to the DAC output.

Avoid crossover of digital and analog signals. Traces on opposite sides of the board should run at right angles to each other. This reduces the effects of feedthrough on the board. A microstrip technique is by far the best but not always possible with a double-sided board. In this technique, the component

side of the board is dedicated to ground plane, whereas signal traces are placed on the solder side.

DC-to-DC Converters

To achieve high efficiency, good regulation, and stability, a well-designed printed circuit board layout is required.

Follow these guidelines when designing printed circuit boards (see Figure 80):

- Keep the low ESR input capacitor, $C_{\rm IN}$, close to $AV_{\rm CC}$ and PGND.
- Keep the high current path from C_{IN} through the inductor, L_{DCDC} , to SW_X and PGND as short as possible.
- Keep the high current path from C_{IN} through L_{DCDC} and the rectifier, D_{DCDC}, to the output capacitor, C_{DCDC}, as short as possible.
- Keep high current traces as short and as wide as possible. The path from $C_{\rm IN}$ through the inductor, $L_{\rm DCDC}$, to SW_X and PGND should be able to handle a minimum of 1 A.
- Place the compensation components as close as possible to COMP_{DCDC x}.
- Avoid routing high impedance traces near any node connected to SW_x or near the inductor to prevent radiated noise injection.

GALVANICALLY ISOLATED INTERFACE

In many process control applications, it is necessary to provide an isolation barrier between the controller and the unit being controlled to protect and isolate the controlling circuitry from any hazardous common-mode voltages that may occur. Isocouplers provide voltage isolation in excess of 2.5 kV. The serial loading structure of the AD5755-1 makes it ideal for isolated interfaces because the number of interface lines is kept to a minimum. Figure 88 shows a 4-channel isolated interface to the AD5755-1 using an ADuM1400. For more information, visit www.analog.com.

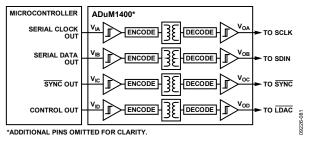
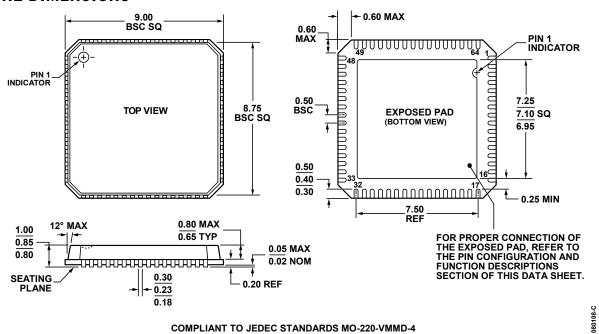


Figure 88. Isolated Interface

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-VMMD-4

Figure 89. 64-Lead Lead Frame Chip Scale Package [LFCSP_VQ] $9\,\mathrm{mm} \times 9\,\mathrm{mm}$ Body, Very Thin Quad (CP-64-3) Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Resolution (Bits)	Temperature Range	Package Description	Package Option				
AD5755-1ACPZ	16	−40°C to +105°C	64-lead LFCSP_VQ	CP-64-3				
AD5755-1ACPZ-REEL7	16	-40°C to +105°C	64-lead LFCSP_VQ	CP-64-3				
EVAL-AD5755-1SDZ			Evaluation Board					

¹ Z = RoHS Compliant Part.

